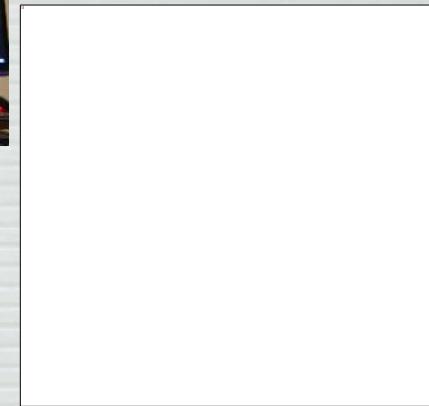


Digital microscopy: Light Sources and Detectors

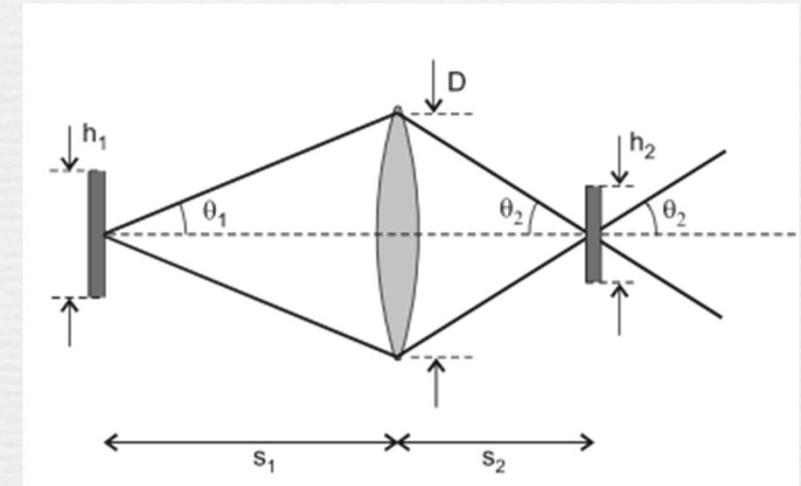


Nico Stuurman, UCSF/HHMI
UCSF, April 2013

Light Sources

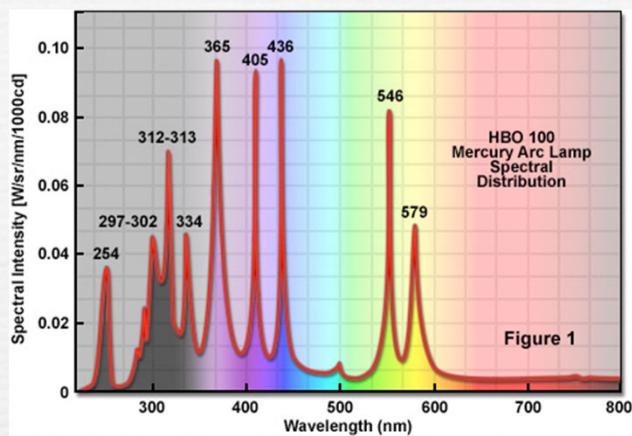
Factors to consider:

- Desired Wavelength (Color)
- Brightness
 - ◆ Inherent Brightness
 - ◆ Angle!!!
 - ◆ Delivery
- Uniformity
- (Computer) Control

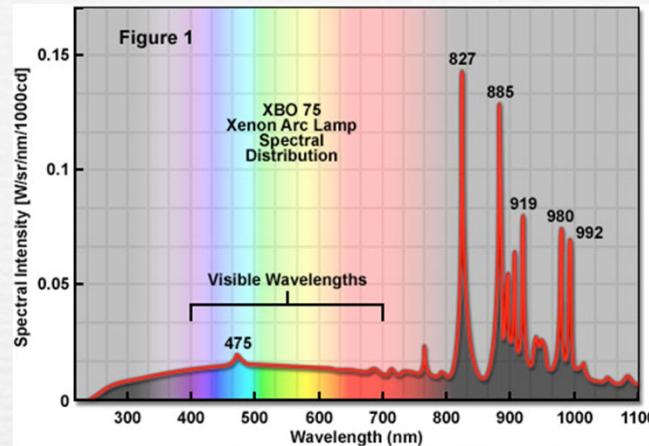


Brightness is determined by size and angle

Arc Lamps



Mercury Arc



Xenon Arc



Cons:

- Short Lifetime
- Dangerous (Hg)
- Hot
- Needs mechanical shutter
- Laborious installation



Copyright © 1995-2000 Arisian Scientific

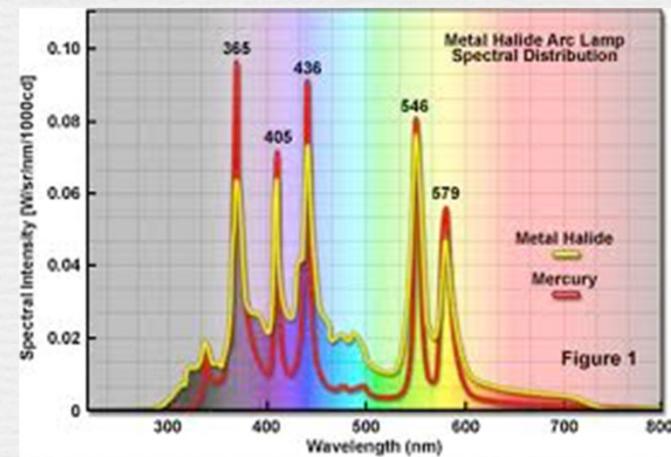
Metal Halide

Produces light by an electric arc through a gaseous mixture of vaporized mercury and metal halides (compounds of metals with bromine or iodine).

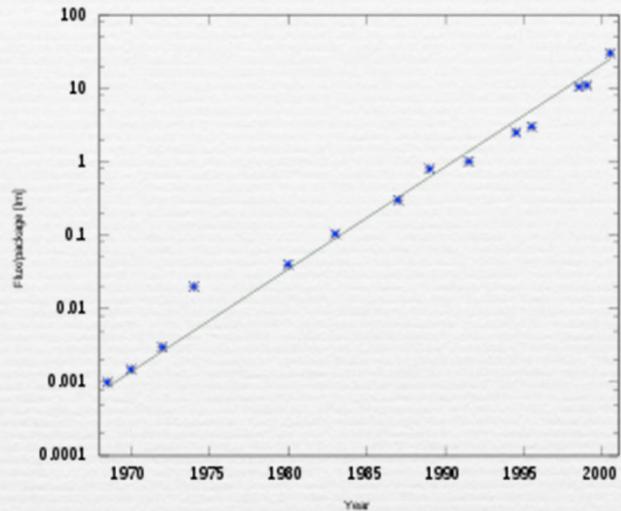


Step up from Arc lamps, still:

- Hot, loud, lifetime ~1500 hours
- Lamps expensive (\$500-800)
- Needs mechanical shutter



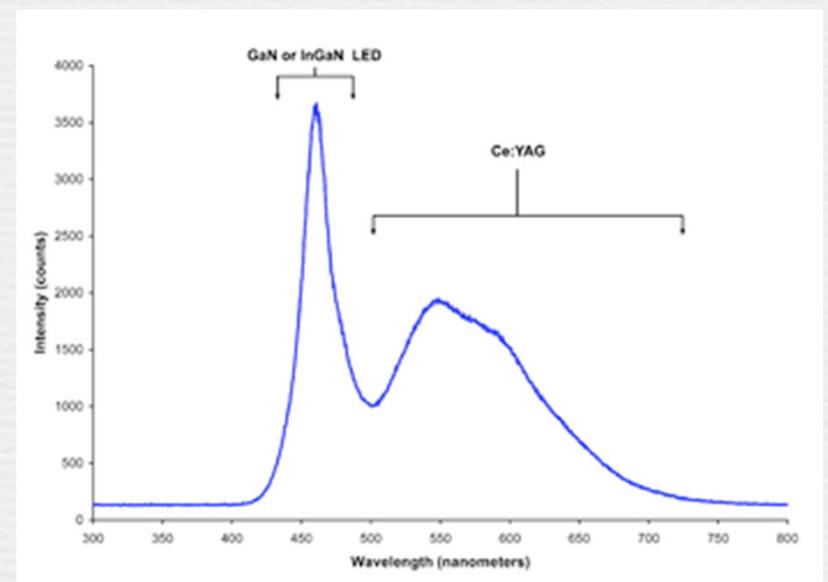
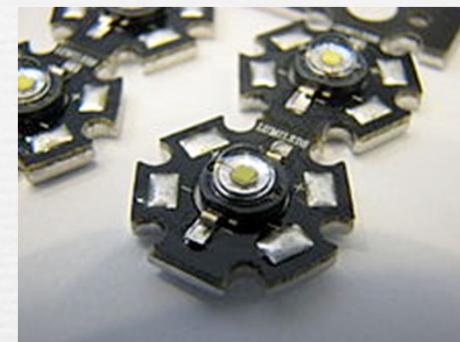
LEDs



Haitz's law: Every decade the cost per lumen falls a factor of 10,
amount of light increases a factor of 20



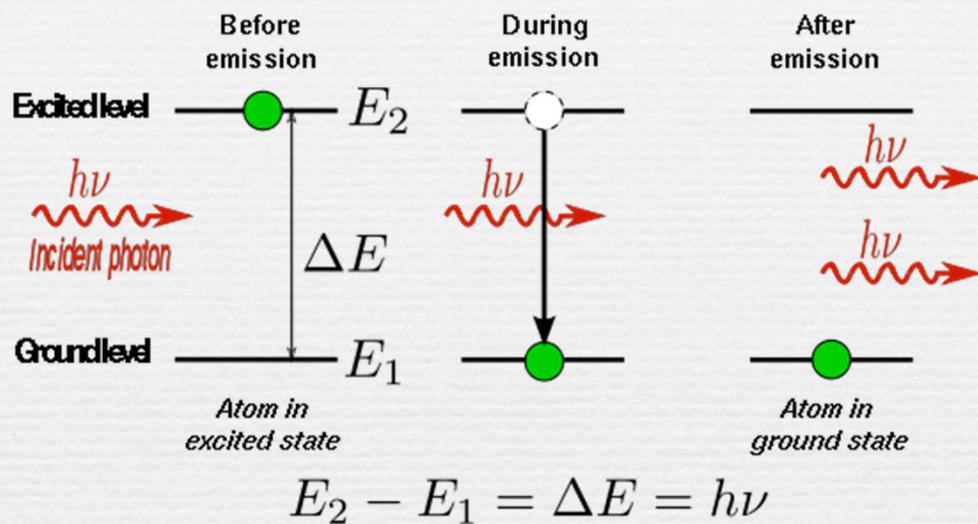
Source: www.cooled.com



White LED with phosphors

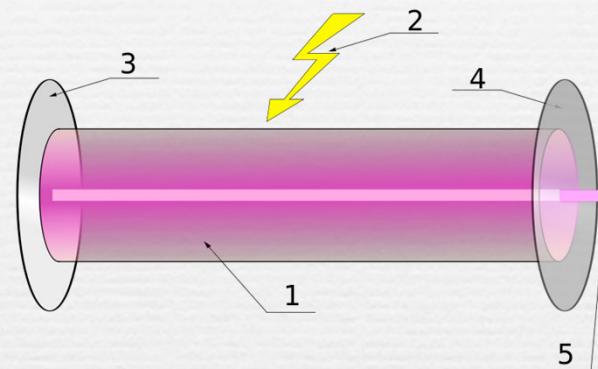
Lasers

Stimulated Emission



From Wikipedia

Principle



1. Gain Medium
2. Laser pumping energy
3. Reflector
4. Output Coupler
5. Laser Beam

From Wikipedia

Coherent (speckles), Collimated
> Dangerous!

Lasers

Ion gas Lasers, Argon, Krypton, HeNe



Argon: 476, 488, 514nm

Krypton: 568, 647nm

HeNe: 632nm

pumped by electric discharge

- Inefficient > Hot and Loud
- No modulation
- No longer legal?
- Very nice beam quality

Lasers

Solid-state lasers

Optically pumped

Laser Diode
(electrically pumped)



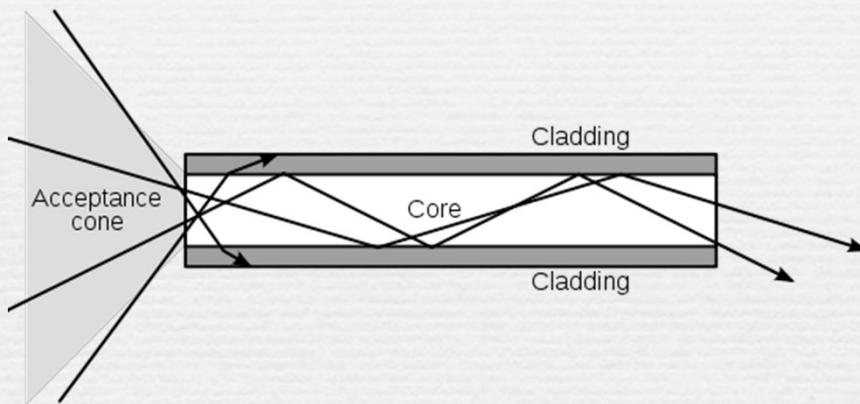
Can be modulated

No good yellow (560nm) line?

- Highly efficient, small form factor
- Some can be electrically modulated
- Beam quality good enough

Lasers, coupling

Optical Fibers

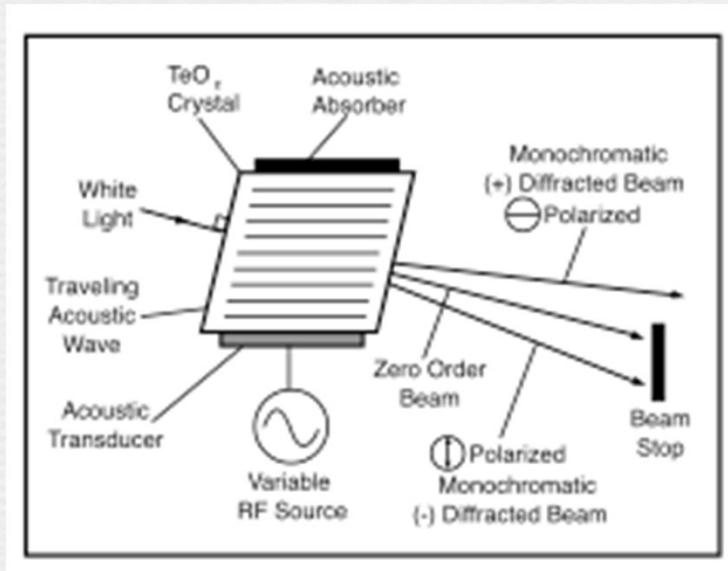


Multi Mode - core > 10 microns

Single Mode - core 3-6 micron (visible)

Lasers, modulation

- Direct (if possible)
- Mechanical shutter
- AOM or AOTF



Acousto Optical Tunable Filter

- Piezoelectric Optical Device
- Switches and modulates intensity
- Fast! (sub-microseconds)
- Mainly used for excitation laser light
- Polarization depended

Also: AOM or Bragg cell

Imaging Detectors

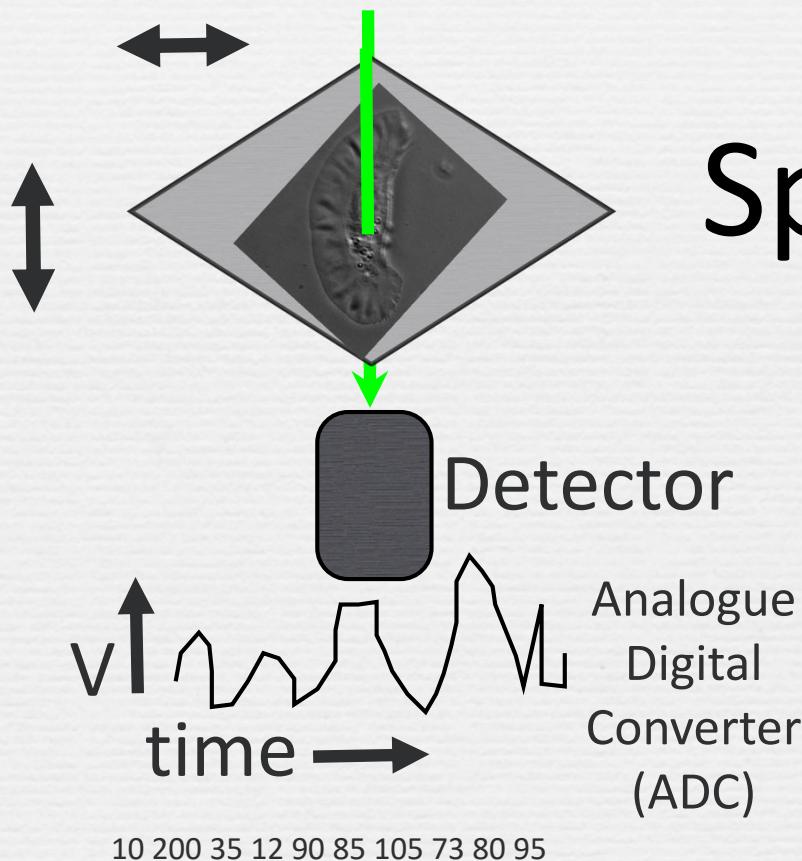
- n Detectors:
 - n ‘Single point’ detectors
 - n ‘Multiple point’ detector
(cameras)



Imaging Detectors

Photon -> Electrons -> Voltage ->Digital Number

Single point detector



Multi point detector (camera)

Speed!

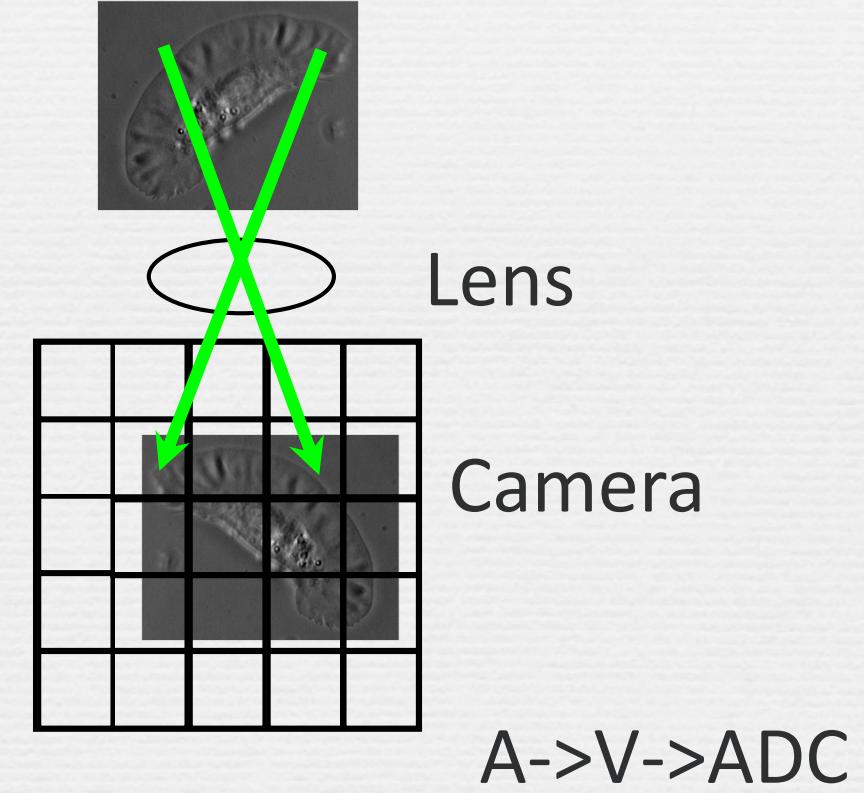
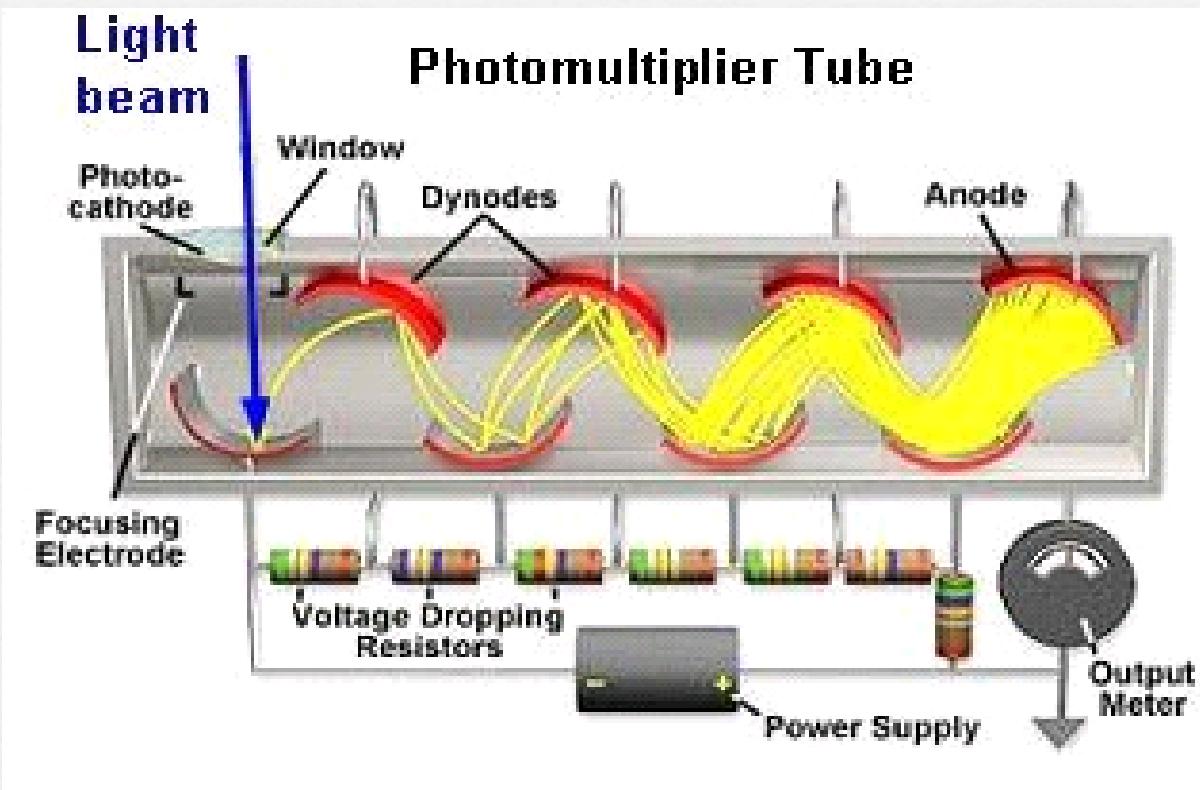
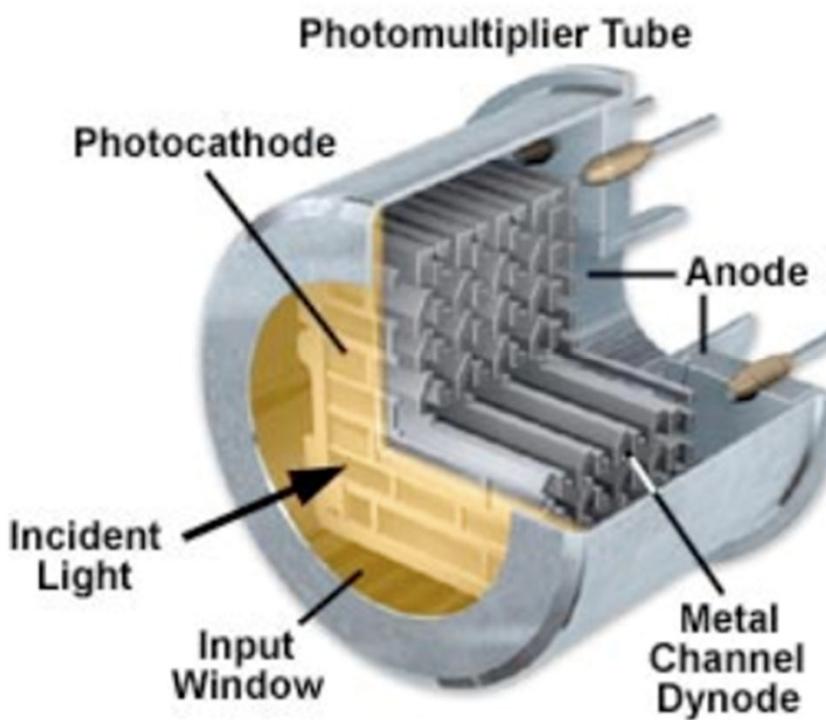


Photo-Multiplier Tube (PMT)



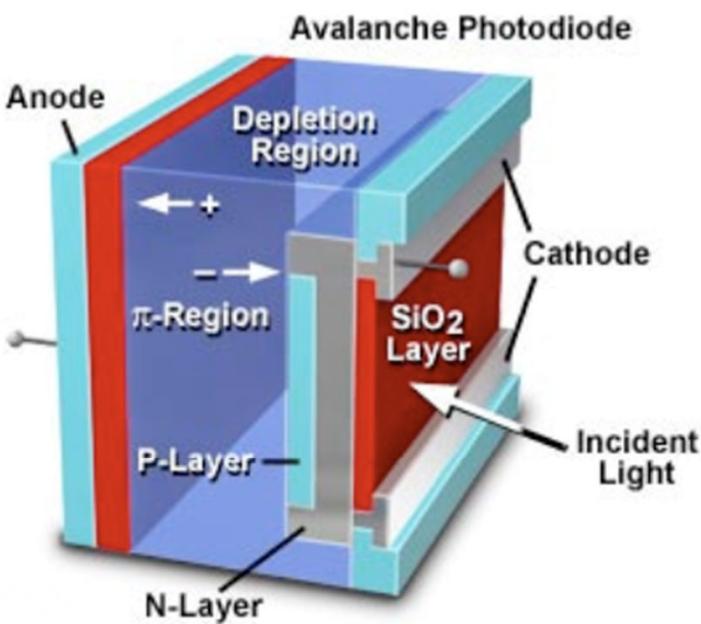
- Very linear
- Very High Gain
- Fast response
- Poor Quantum efficiency (~25%)

PMT modes



- n Photon counting mode:
 - n Count pulses
 - n Zero background
 - n Slow
- n Linear mode
- n Measure current
- n Fast but noisy

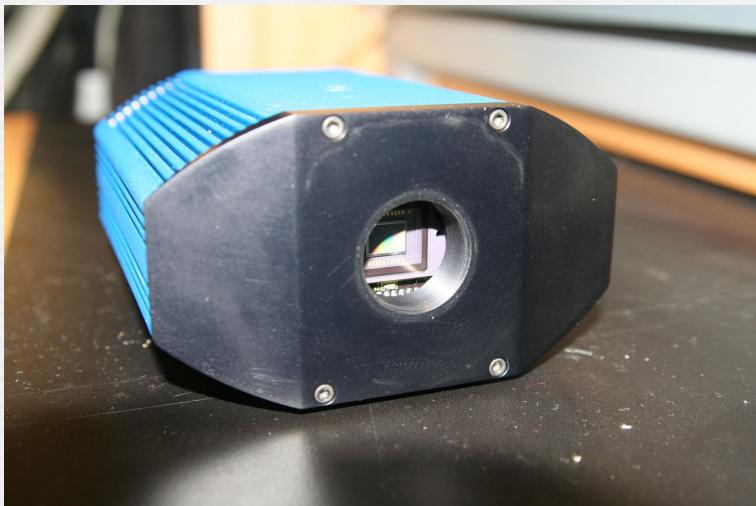
Avalanche Photo Diode



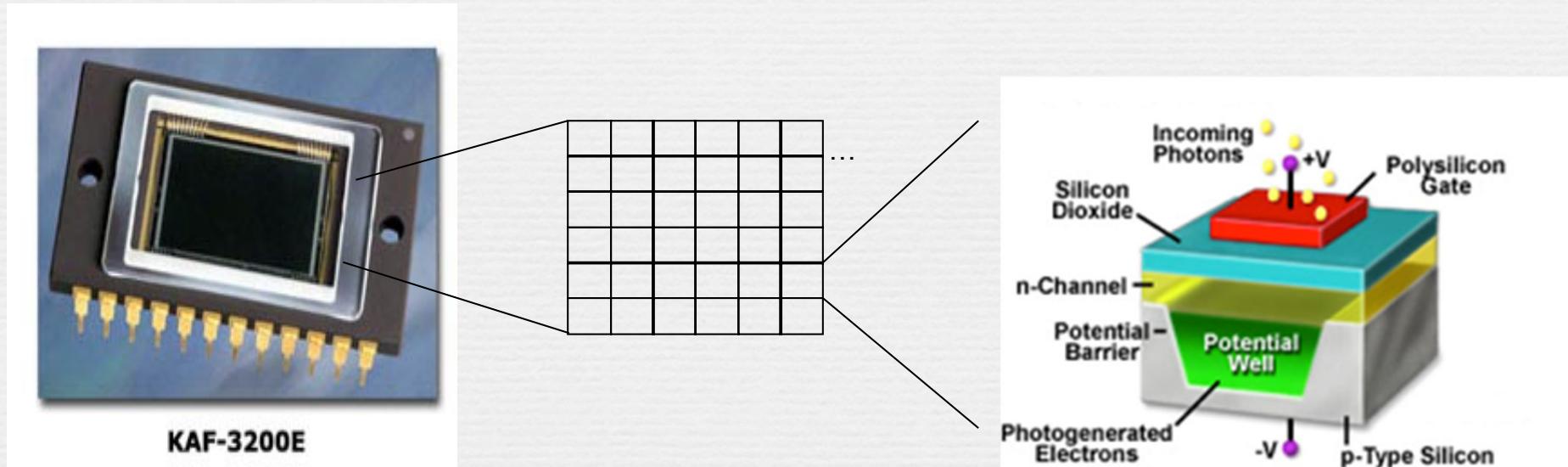
- Absorbed photons->electron
- Electrons amplified by high voltage and ‘impact ionization’
- High QE (~90%)
- Photon-counting ability (different design)
- Overheats if run too fast



Cameras in Microscopy

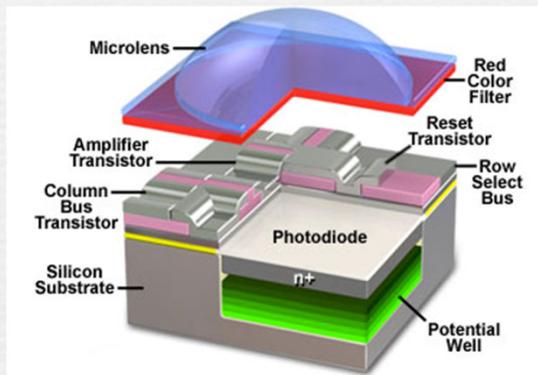


Arrays of photo-sensitive elements



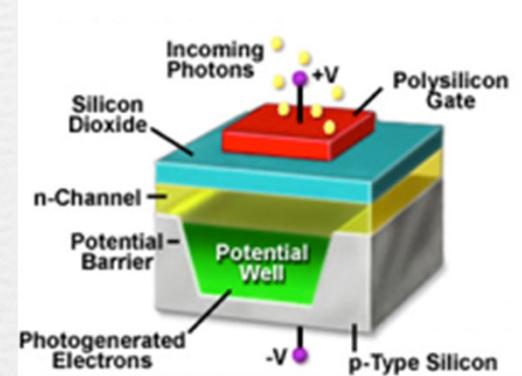
Two Architectures:

Complementary Metal Oxide Semiconductor (CMOS)



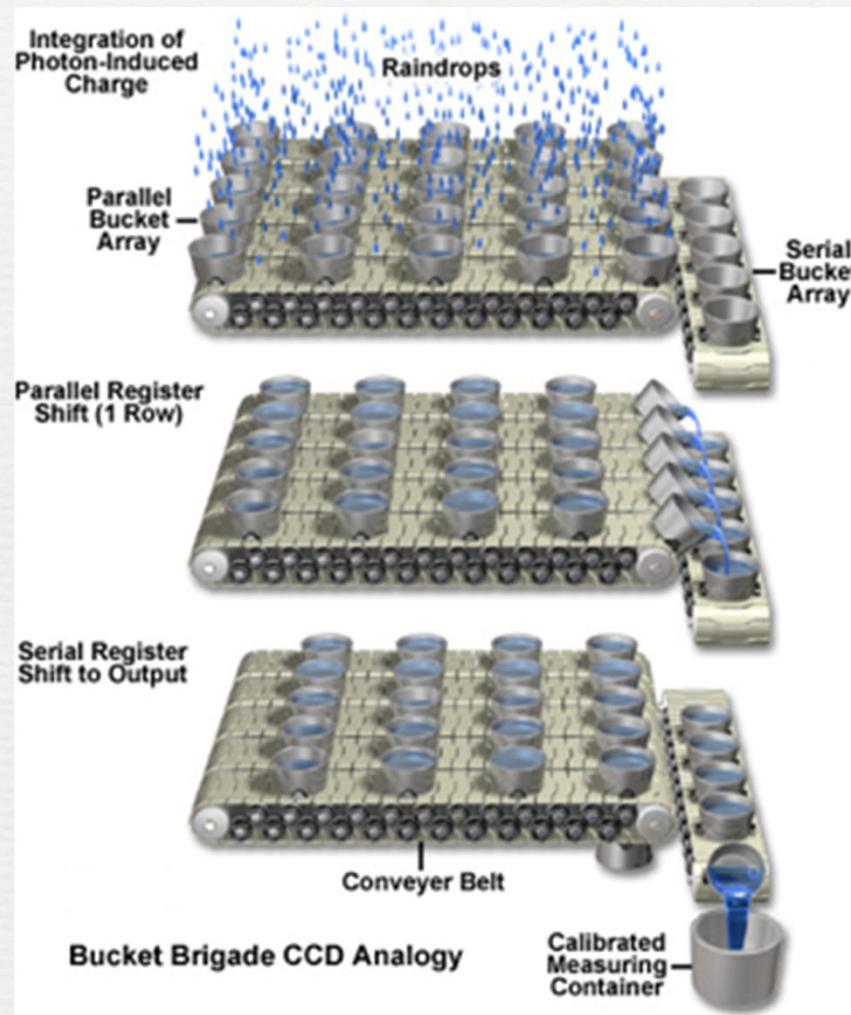
Each pixel has an amplifier
Transfers voltage
Fast
Noisy

Charged Coupled Devices (CCD)



Single read-out
amplifier
Transfers charge
Slow
Precise

CCD readout “bucket-brigade” analogy



CCD Architecture

Plan View

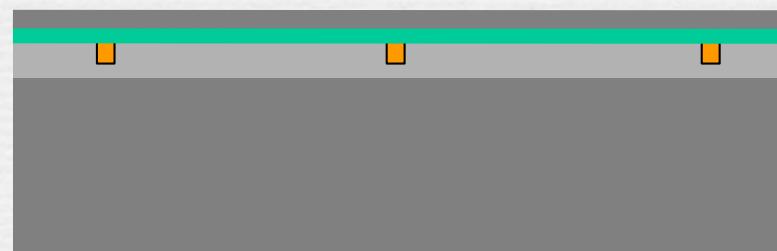
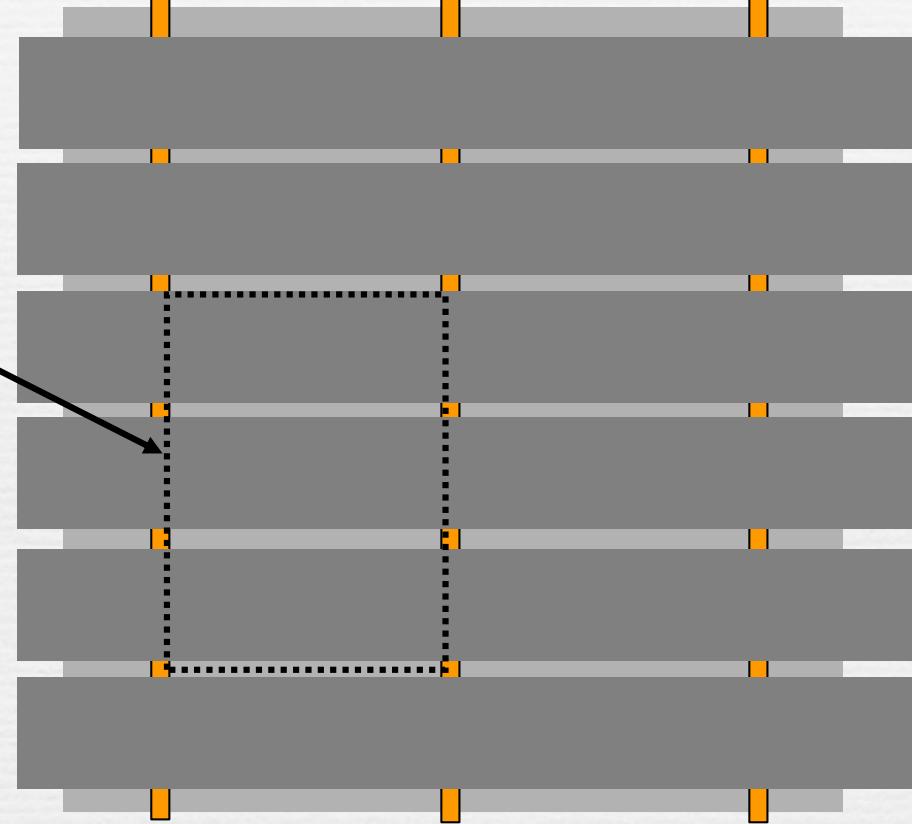
One pixel

Cross section

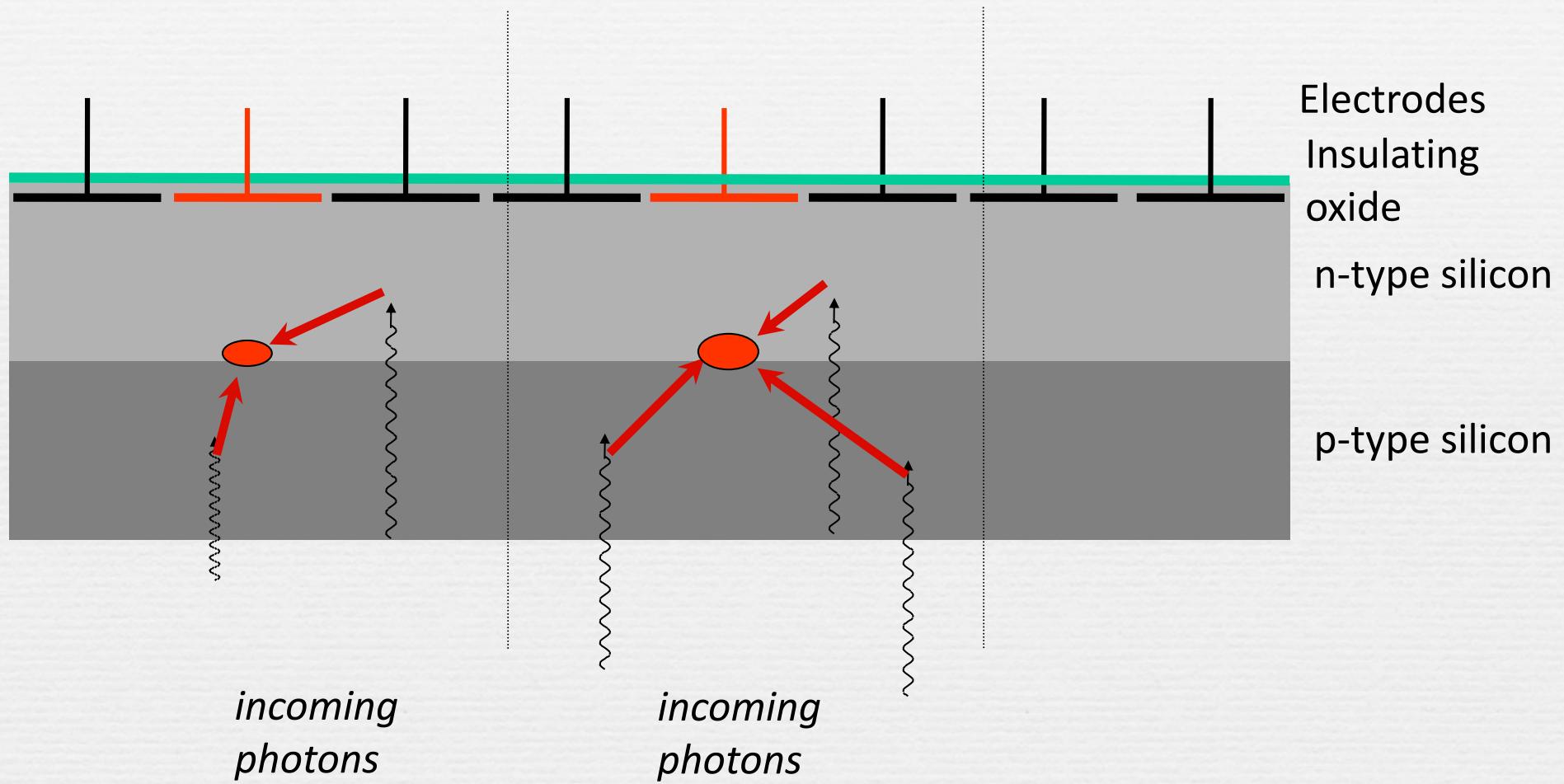
Channel stops define columns of the image

Three transparent horizontal electrodes define the pixels vertically. Transfer charge during readout

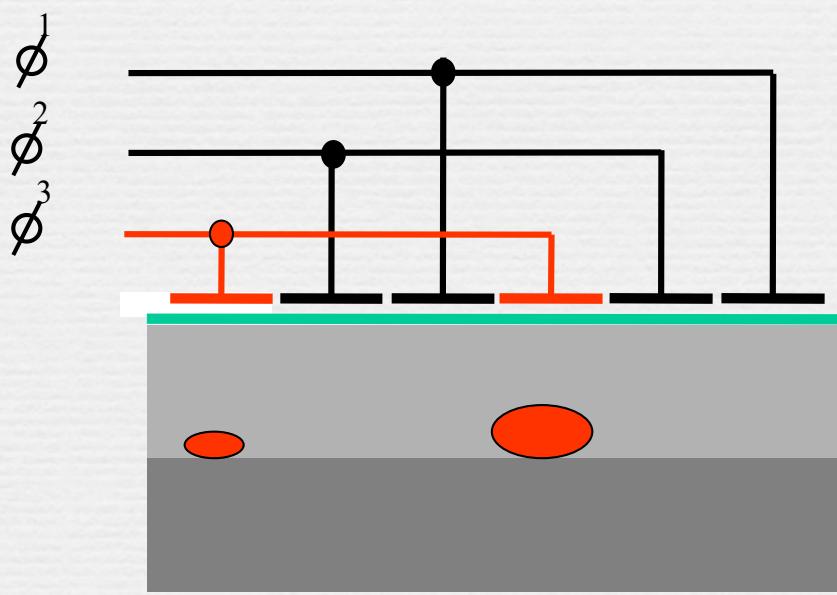
Electrode
Insulating oxide
n-type silicon
p-type silicon



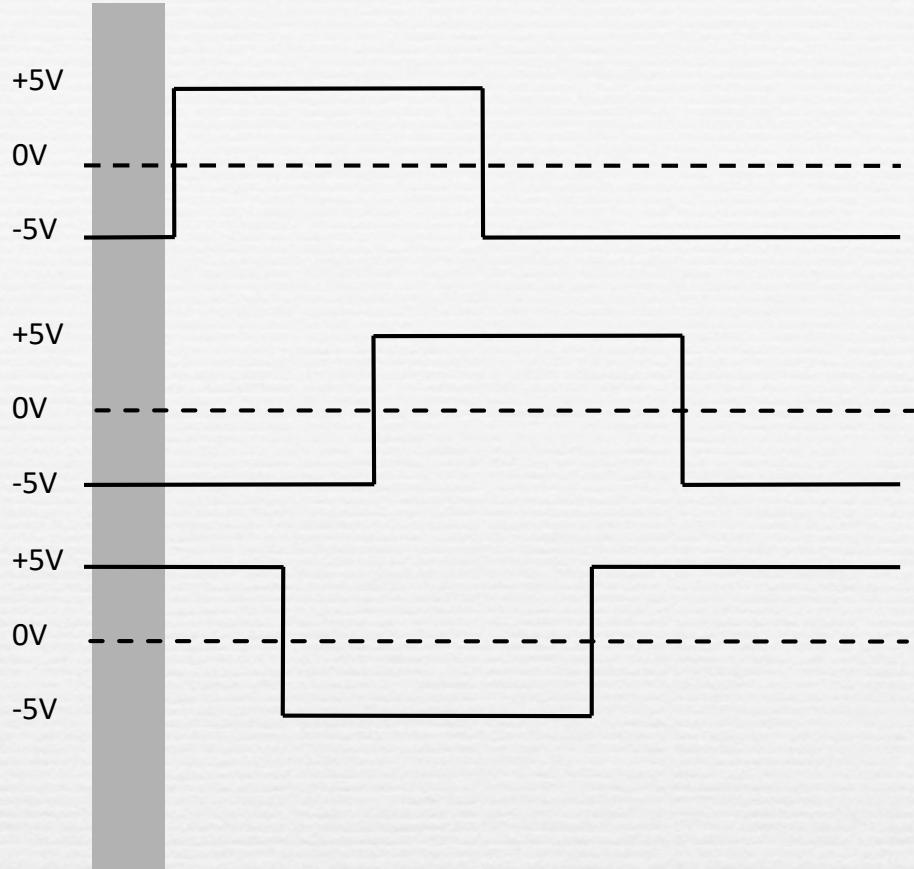
CCD Architecture



Charge Transfer in a CCD

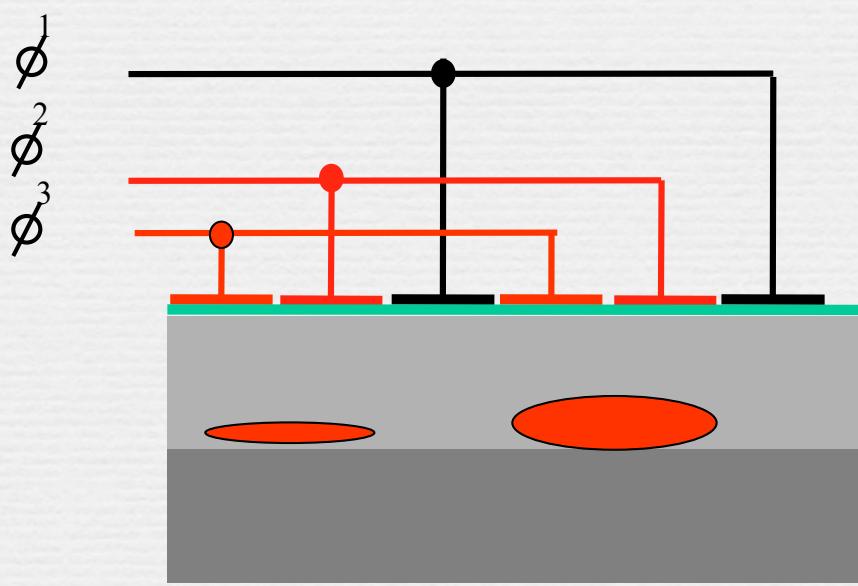


ϕ^1
 ϕ^2
 ϕ^3



Time-slice shown in diagram

Charge Transfer in a CCD

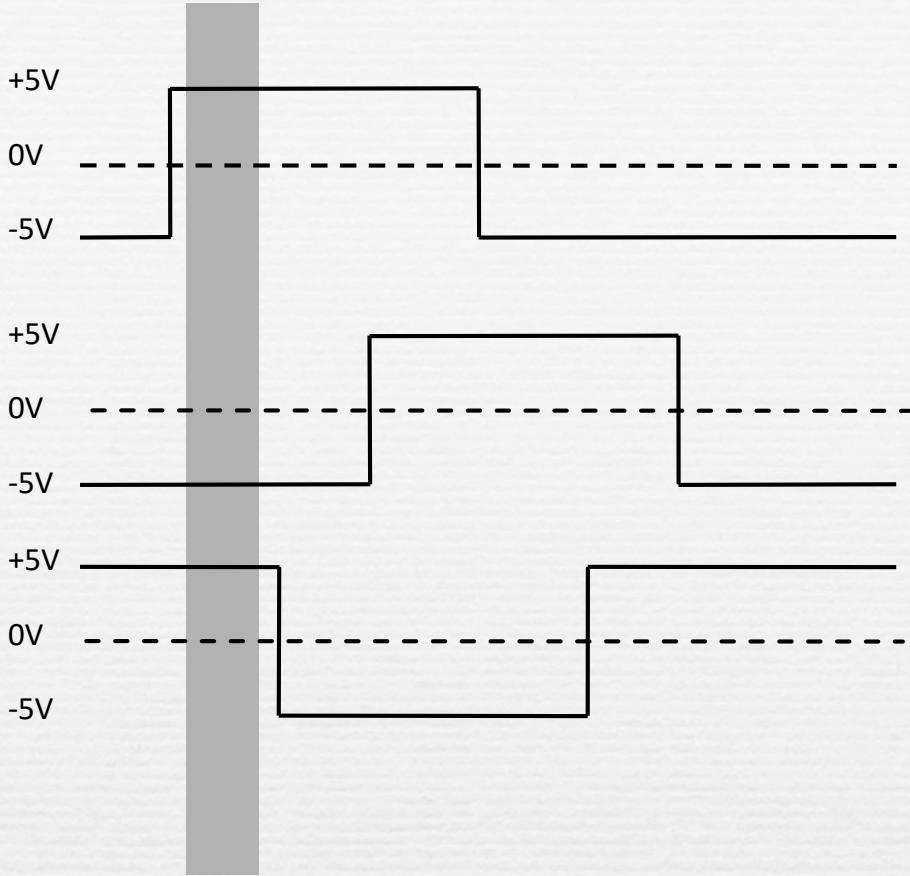


ϕ^2

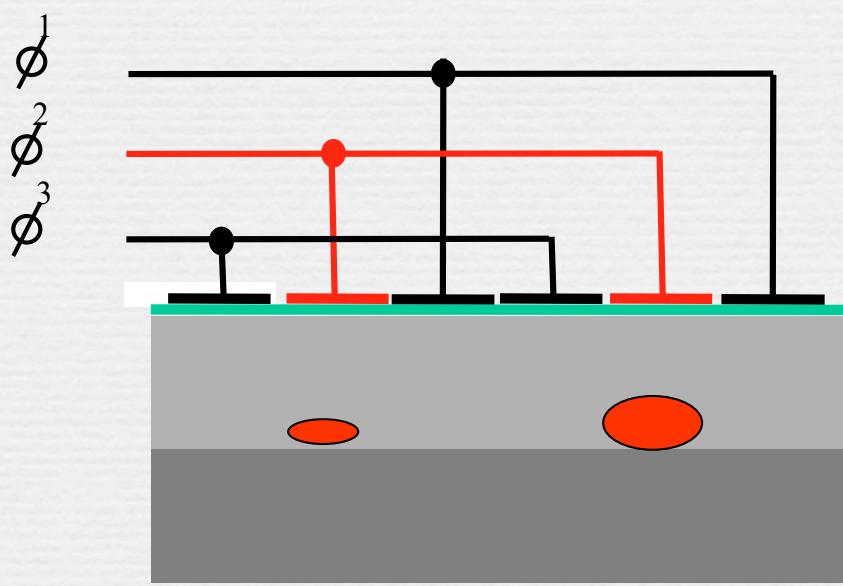
ϕ^1

ϕ^3

Time-slice shown in diagram



Charge Transfer in a CCD

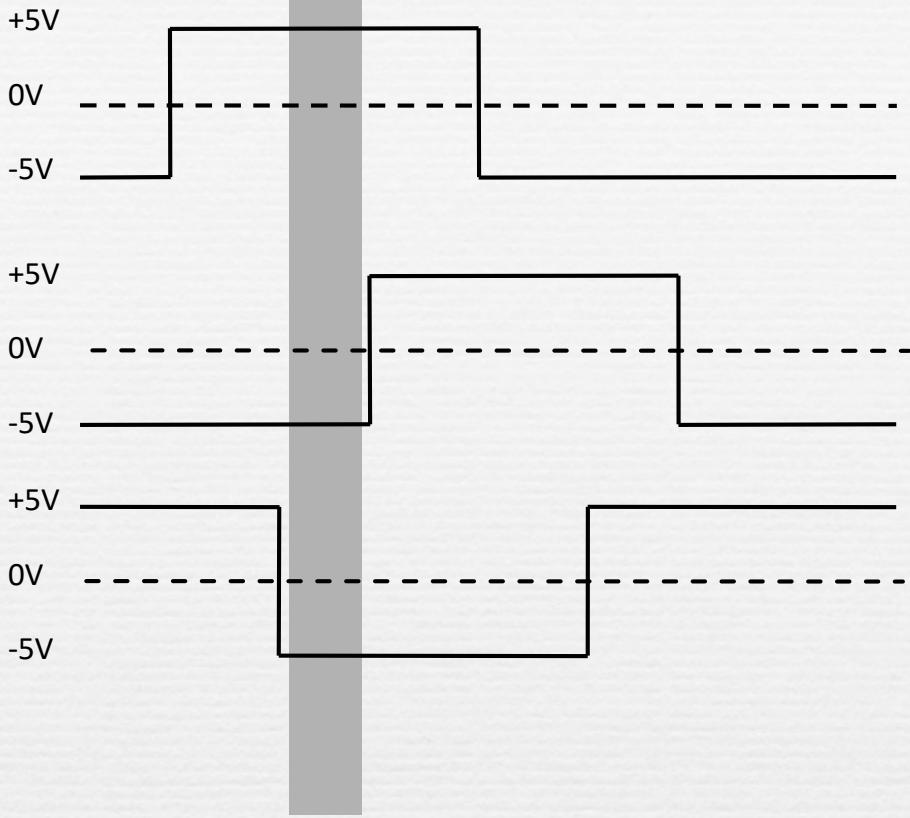


ϕ^2

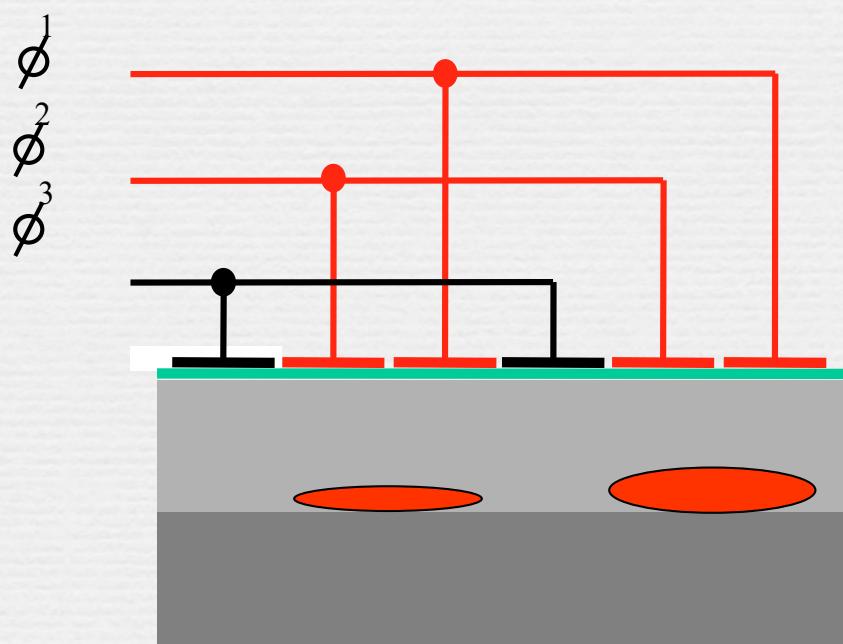
ϕ^1

ϕ^3

Time-slice shown in diagram



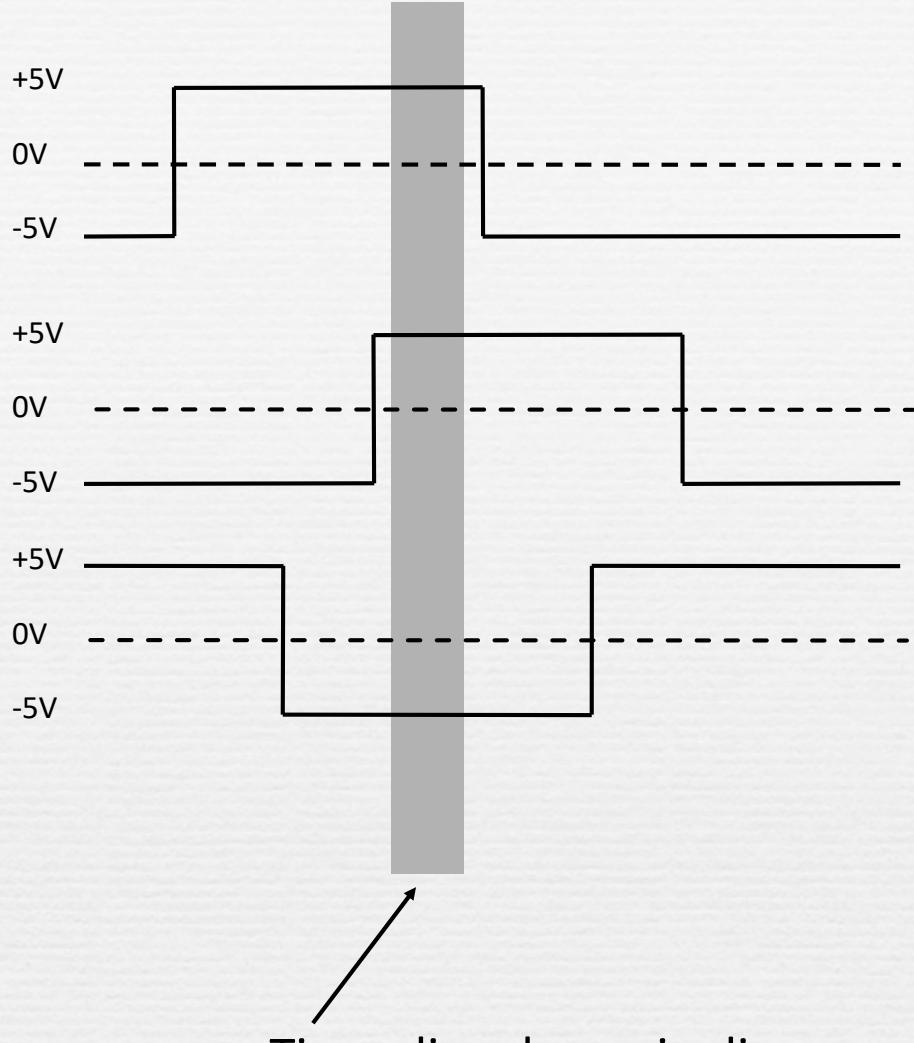
Charge Transfer in a CCD



ϕ^2

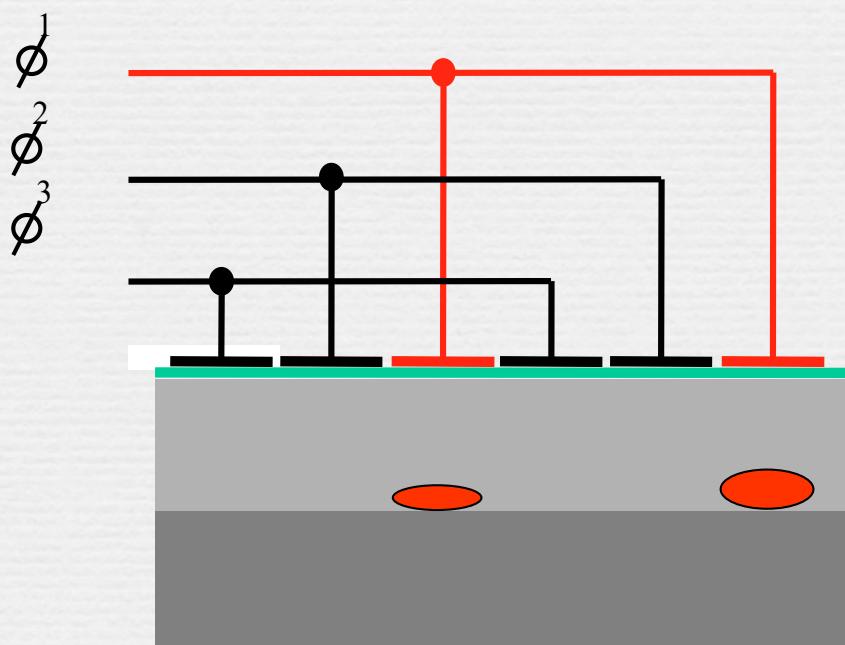
ϕ^1

ϕ^3



Time-slice shown in diagram

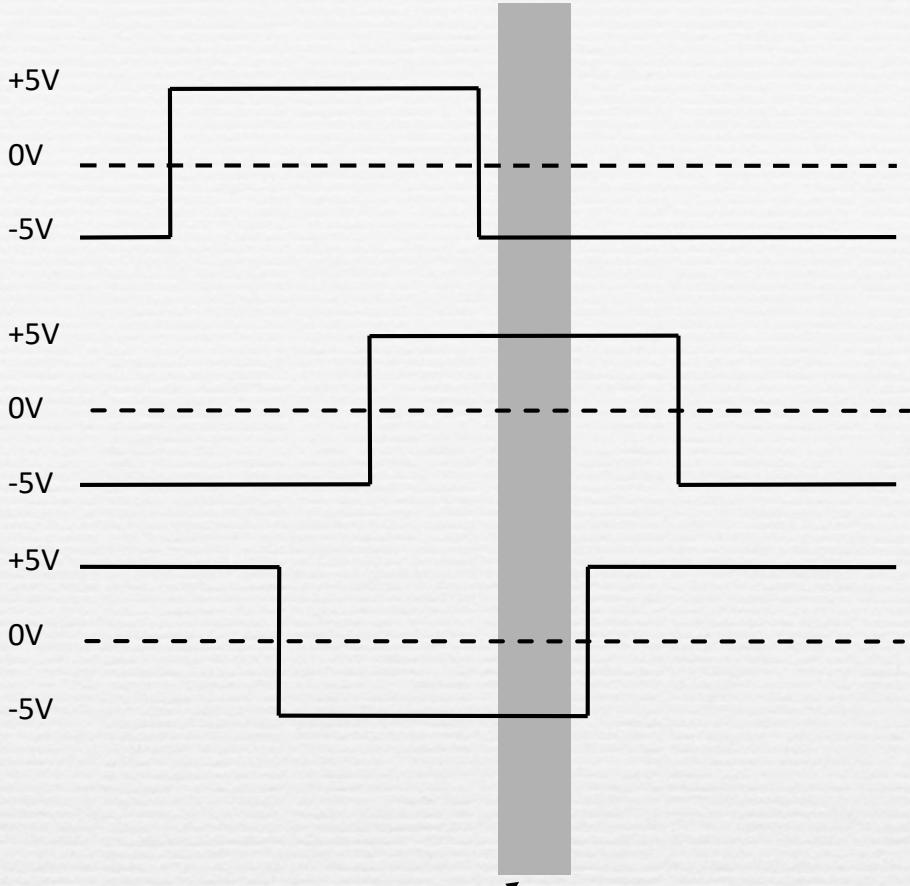
Charge Transfer in a CCD



ϕ^2

ϕ^1

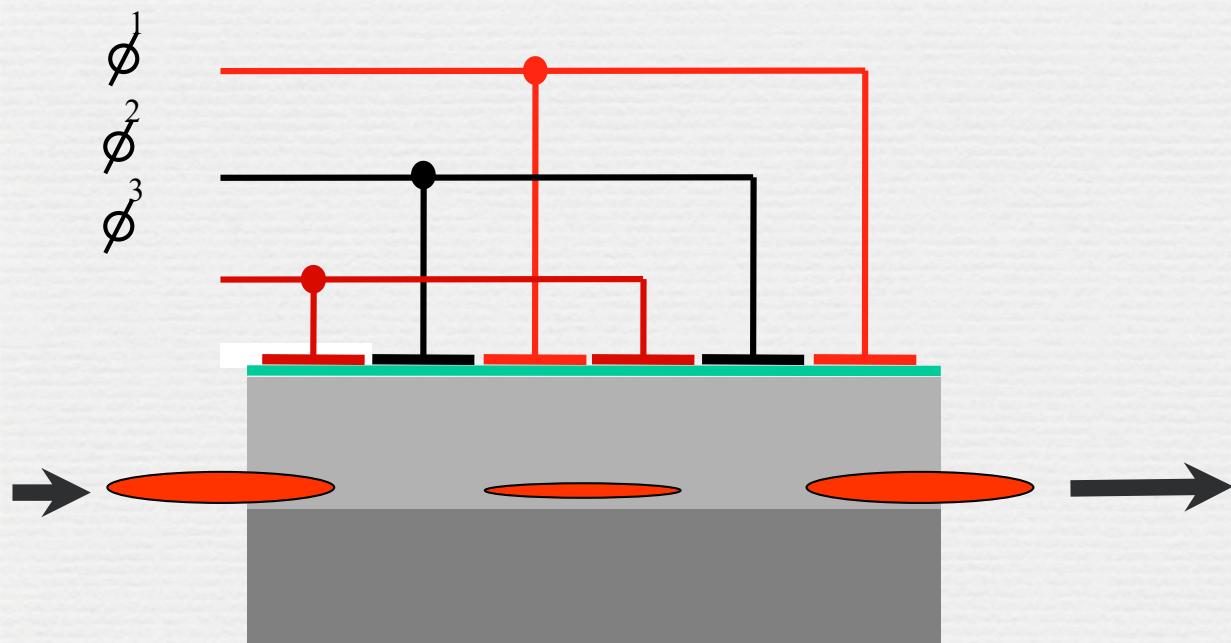
ϕ^3



Time-slice shown in diagram

Charge Transfer in a CCD

Transfer charge to the next pixel

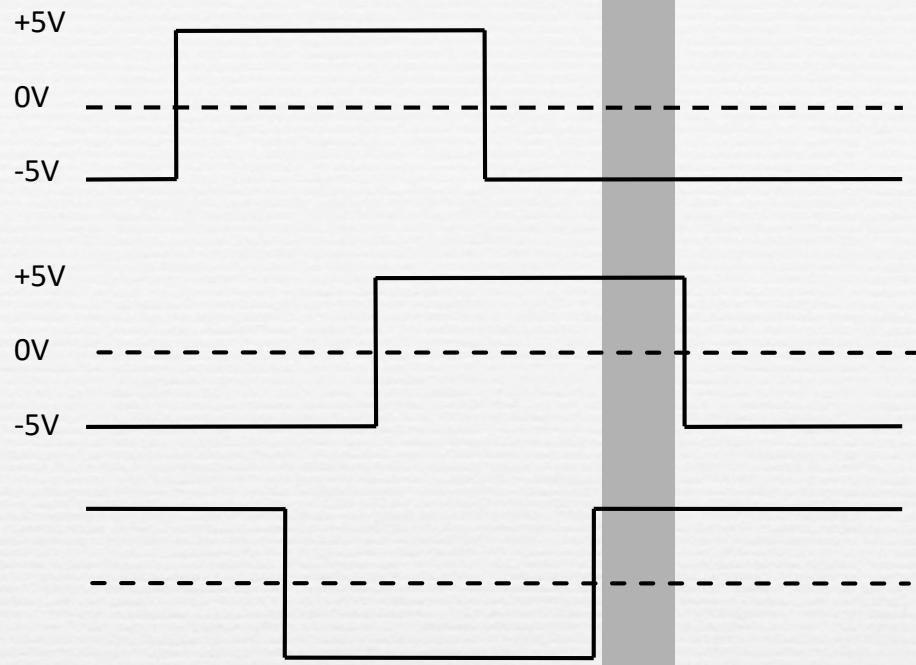


ϕ^2

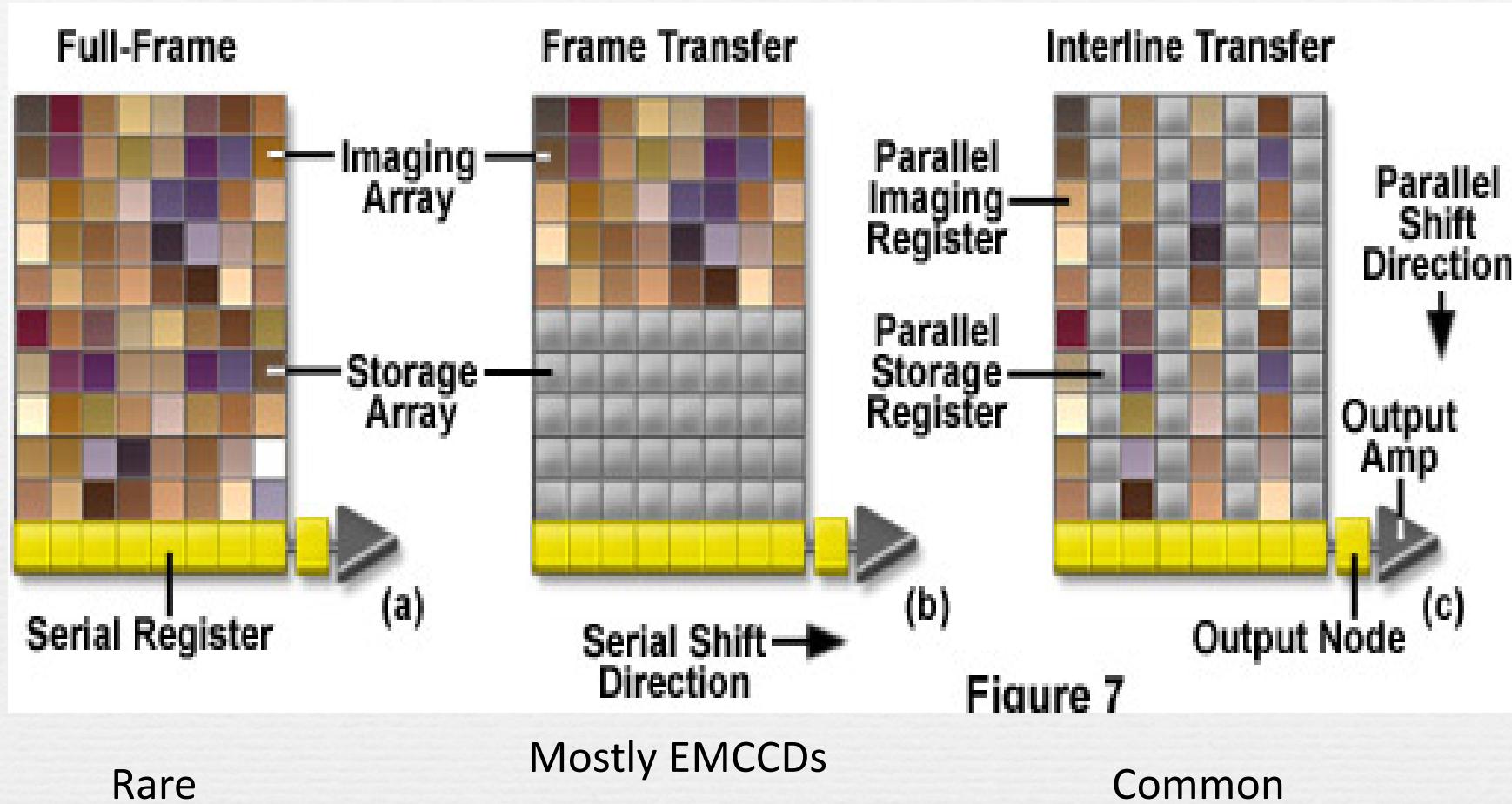
ϕ^1

ϕ^3

Time-slice shown in diagram

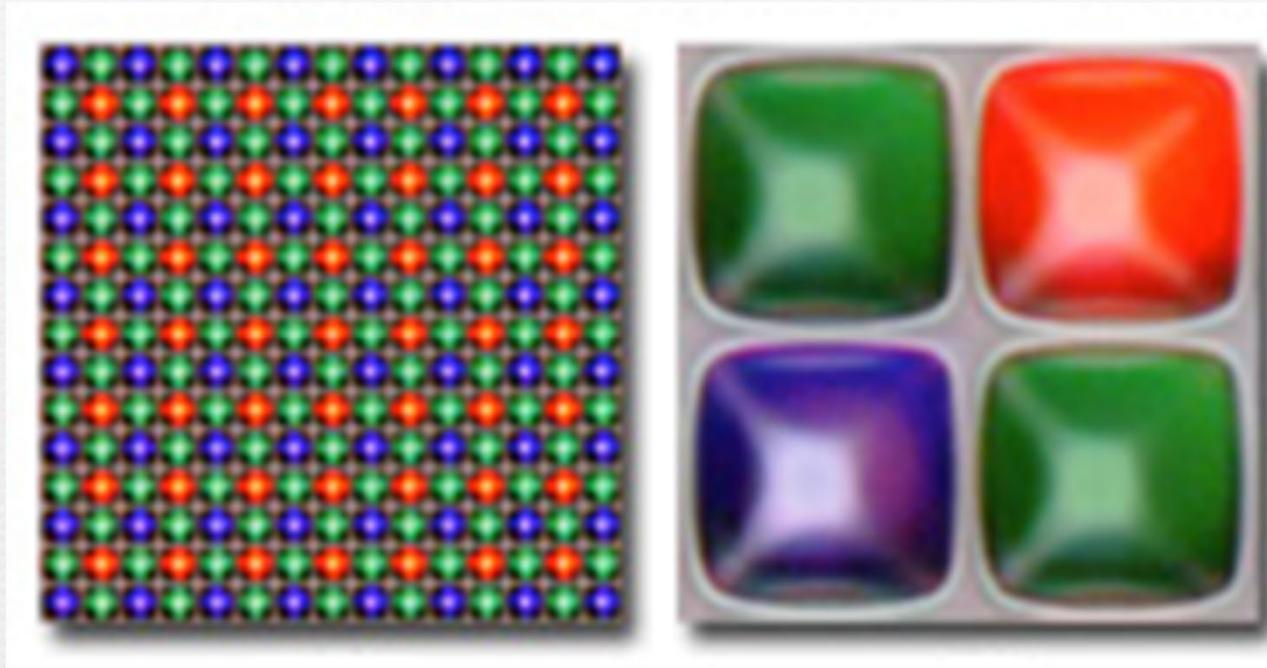


CCD Architectures



Full frame CCDs cannot acquire while being read out;
They also require a mechanical shutter to prevent
smearing during readout.

Why don't we use color CCDs?



- Four monochrome pixels are required to measure one color pixel
- Your 5MP digital camera really acquires a 1.25 MP red and blue image and a 2.5 MP green image and uses image processing to reconstruct the true color image at 5 MP

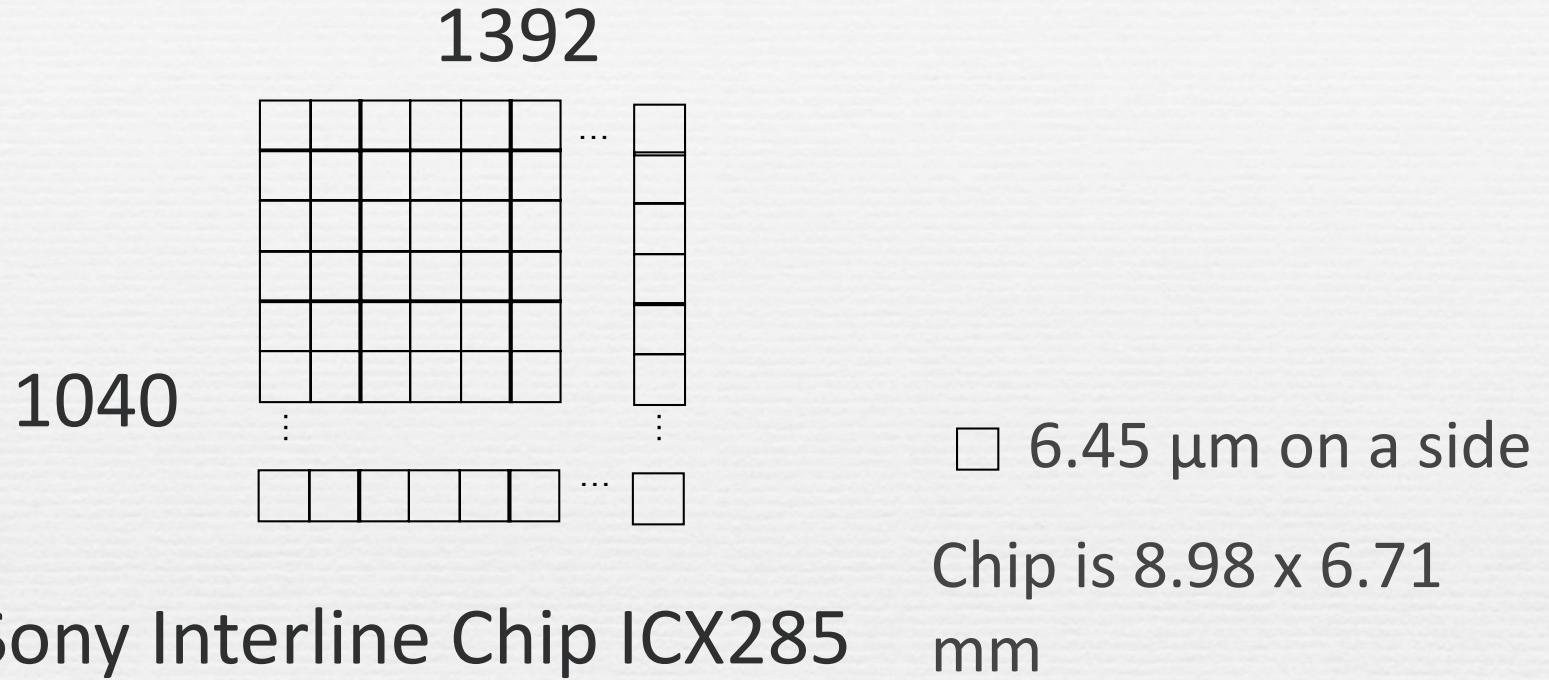
Vital Statistics for CCDs

- Pixel size and number
- Quantum efficiency: fraction of photons hitting the CCD that are converted to photo-electrons
- Full well depth: total number of photo-electrons that can be recorded per pixel
- Read noise
- Dark current (negligible for most biological applications)
- Readout time (calculate from clock rate and array size)
- Electron conversion factor (relate digital

SPECIFICATIONS

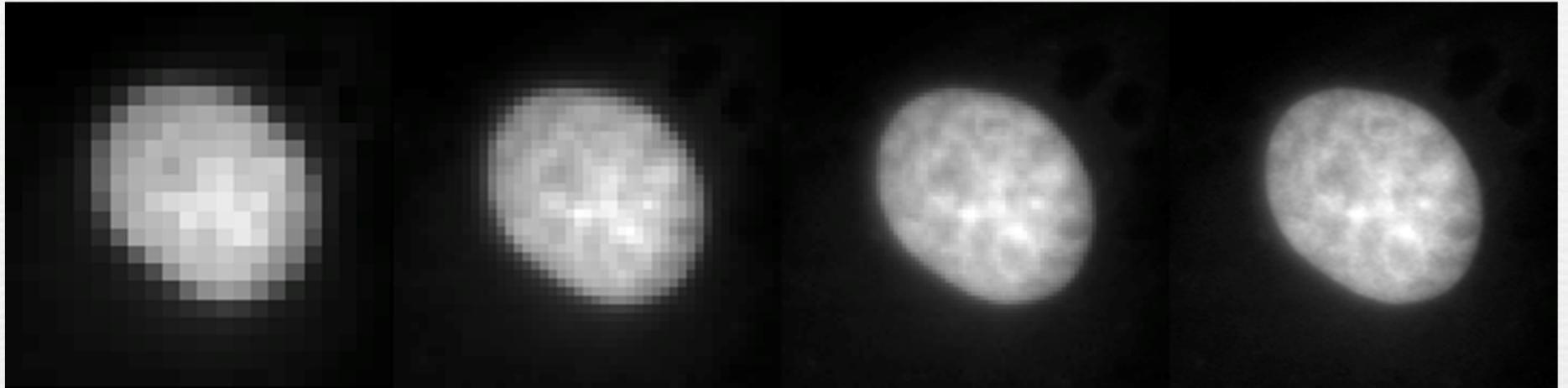
Type number	ORCA-R2 (C10600-10B)	
Camera head type	Hermetic vacuum-sealed head	
Dual cooling	Air cooling / water cooling	
Imaging device	ER-150 progressive scan interline CCD	
Effective number of pixels	1344 (H) X 1024 (V)	
Cell size	6.45 µm (H) X 6.45 µm (V)	
Effective area	8.67 mm (H) X 6.60 mm (V)	
Dual scan mode	Normal scan / Fast scan	
Pixel clock rate	Normal scan	14.00 MHz/pixel
	Fast scan	28.00 MHz/pixel
Readout noise (r.m.s.) typ.	Normal scan	6 electrons
	Fast scan	10 electrons
Full well capacity typ.	High dynamic range mode ①	OFF
		ON
	18 000 electrons	
	36 000 electrons	
Dynamic range typ. ②	3 000 : 1 (at Normal scan / 1X1)	
Cooling method / temperature	Forced-air cooled	- 35 °C
	Water cooled	- 40 °C (Water temperature : +20 °C)
Dark current	0.0005 electrons/pixel/s (at - 40 °C)	
Dual A/D converter	12 bit or 16 bit	
Exposure time	10 µs to 4200 s	
Binning	2 X 2, 4 X 4, 8 X 8	

Pixel size and Resolution



Typical magnification from sample to camera is roughly objective magnification, so 100x objective -> 65nm per pixel

Resolution and magnification

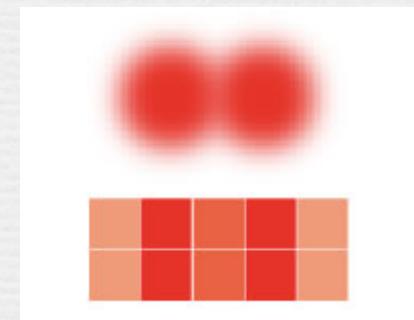


More pixels / resolution element

Where is optimum?

Digital Sampling

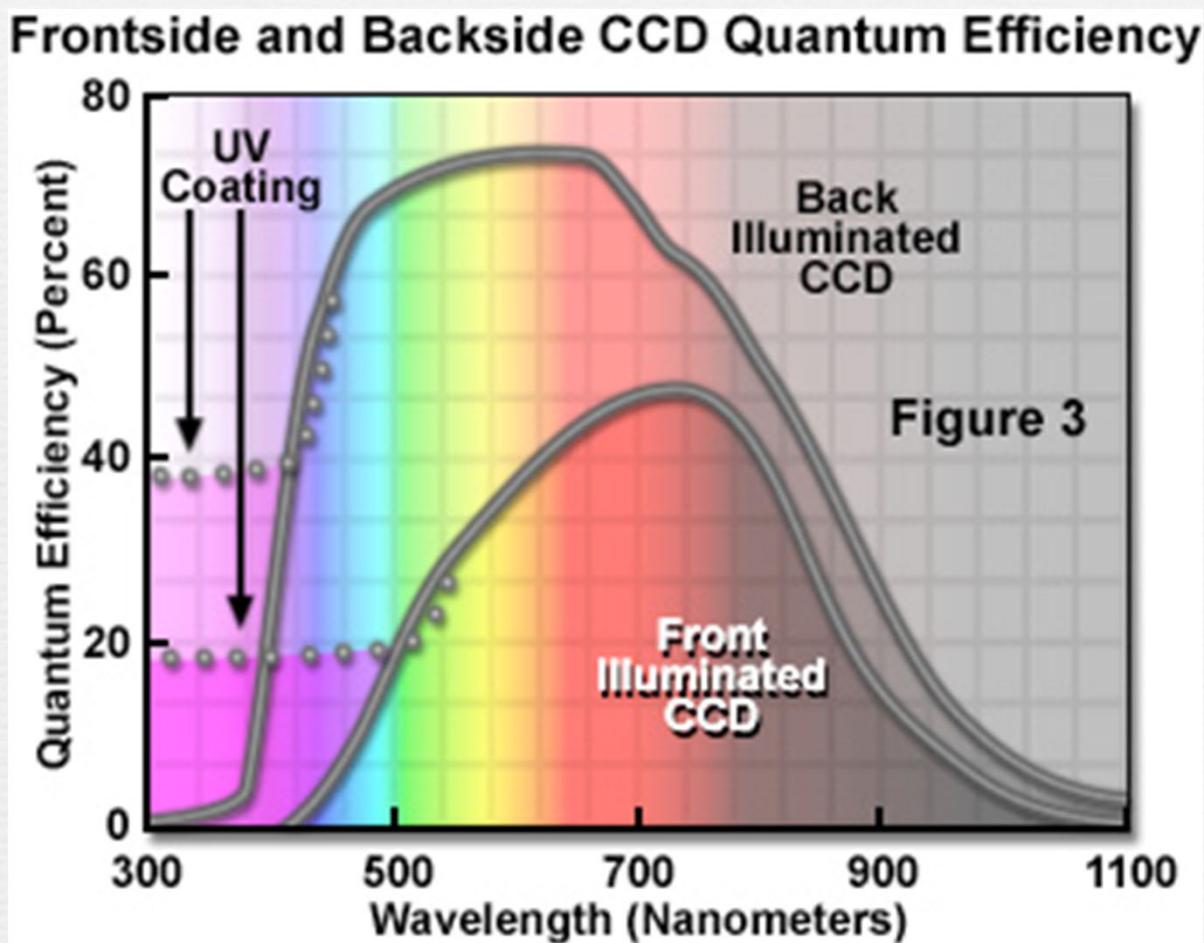
- How many CCD pixels are needed to accurately reproduce the smallest object that can be resolved by the scope?
- Nyquist-Shannon Sampling theorem:
Must have at least two pixels per resolvable element
2.5 – 3 is preferable



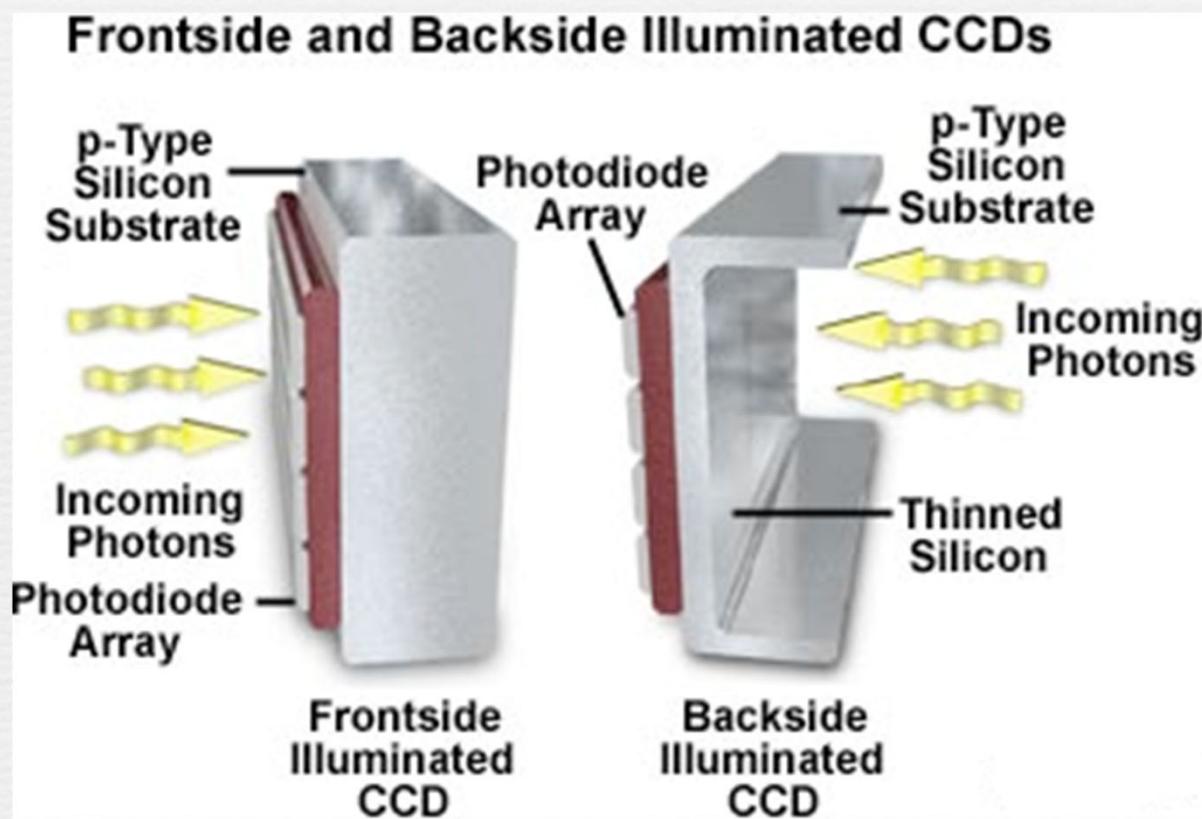
A resolution-centric view of imaging

- Resolution is a function of the objective NA and wavelength (e.g. 1.4 NA with 500 nm light -> \sim 220 nm resolution)
- To achieve this resolution, 220 nm in your image must cover 2 pixels
- Choose your magnification to achieve this
- For 6.45 μm pixels, we need a total magnification of $6450/110 = 58.6$
- So for 1.4 NA, a 40x lens would be under-sampled, a 60x would be just at the Nyquist limit, and a 100x lens would oversample

Quantum Efficiency

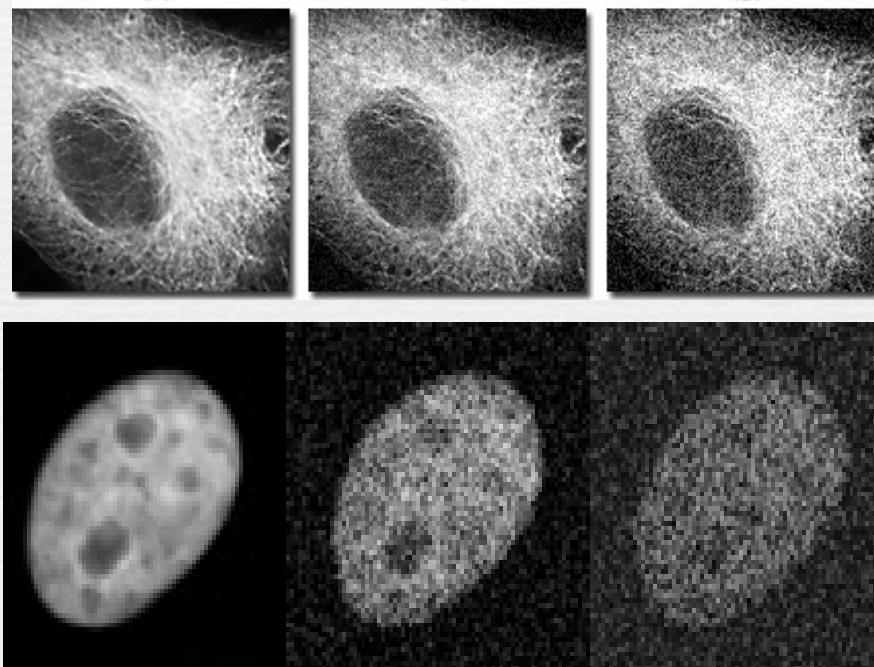


Back-thinning increases QE



Noise

- „ Longer exposure times are better – why?



Decreasing exposure time →

Noise

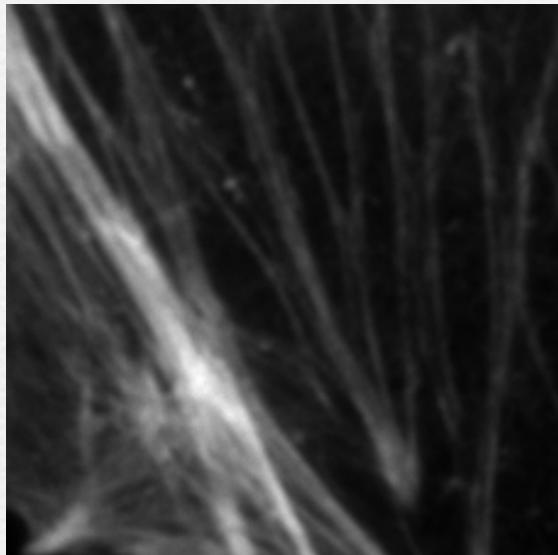
- Photon Shot Noise: Due to the fact that photons are particles and collected in integer numbers. Unavoidable!
 - Scales with $\sqrt{}$ of the number of photons
- Read noise - inherent in reading out CCD
 - Faster -> Noisier
 - Independent of number of photons
- Fixed Pattern Noise - Not all pixels respond equally!
 - Scales linearly with signal
 - Fix by flat-fielding
- Dark current – thermal accumulation of electrons
 - Cooling helps, so negligible for most applications

Signal/Noise Ratio (SNR)

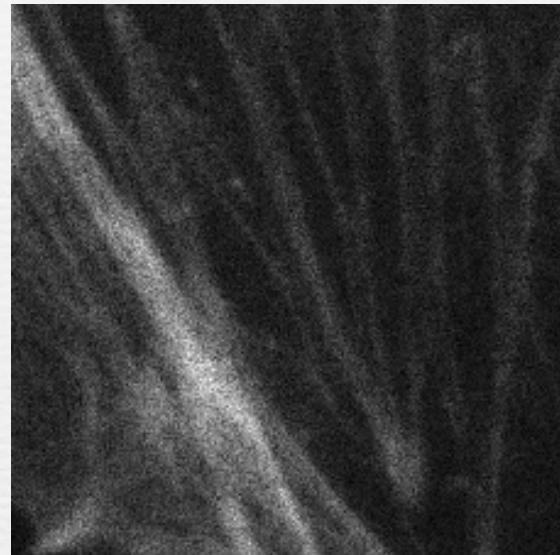
- Signal = # of photons = N
- Noise = $\sqrt{(\text{read noise}^2 + N)}$
- When # of photons << read noise² -> Read noise dominates
- When # of photons >> read noise² -> Shot noise dominates
- When shot noise dominates (Signal/Noise = N/\sqrt{N}), to double your SNR, you need to acquire four times as long (or 2x2 bin)

Often, read-noise dominates

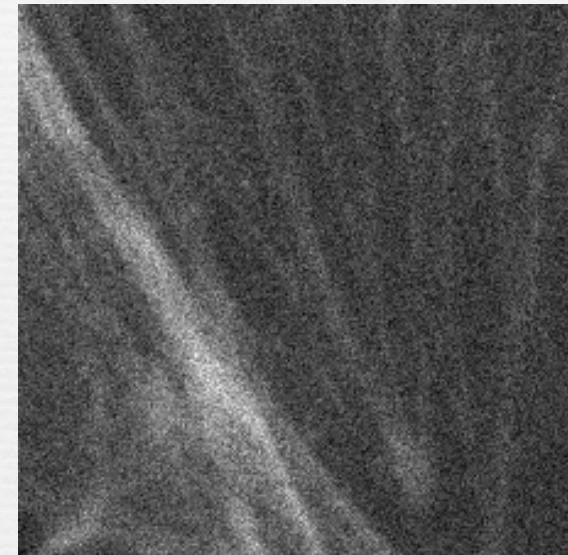
10 photons / pixel on average; ~50 in brightest areas



Test image



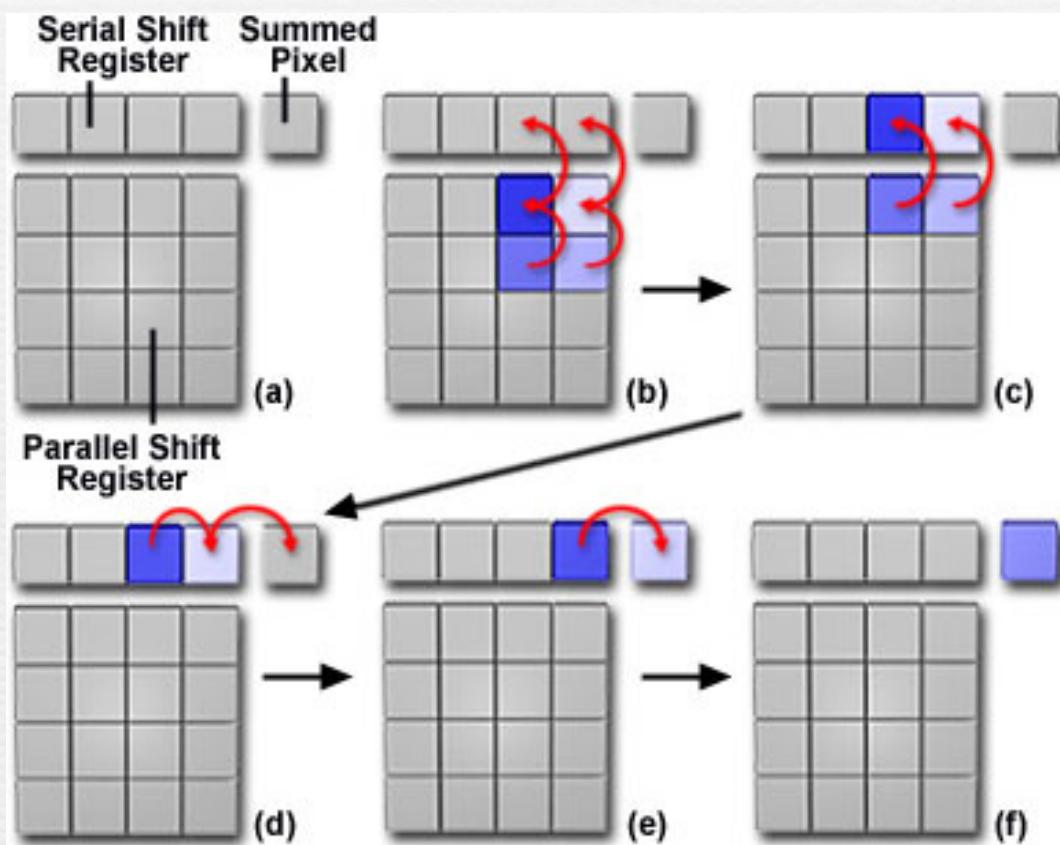
no read noise



5 e⁻ read noise

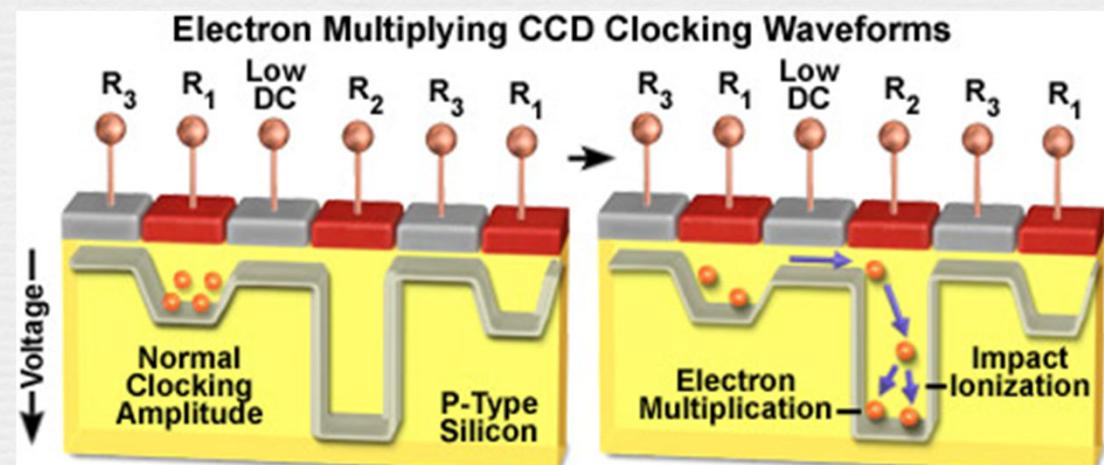
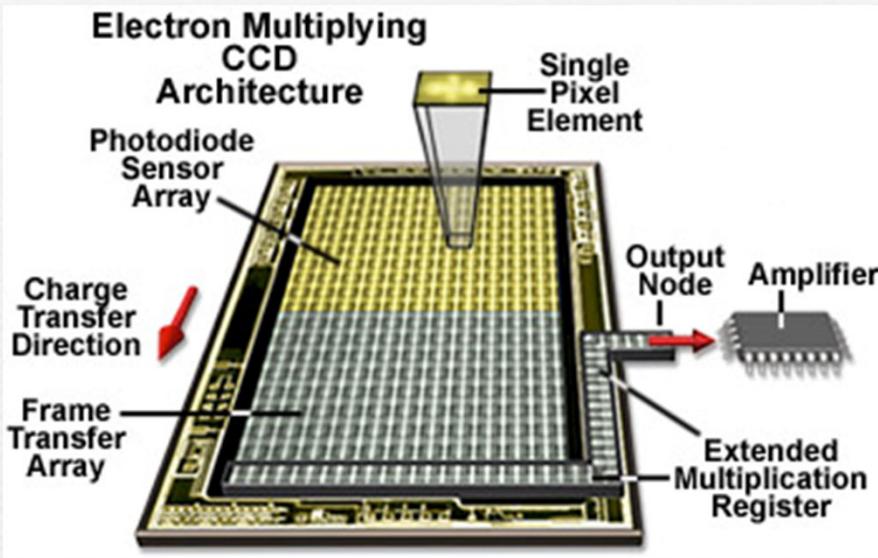
Photon shot noise \sim 3/5 read noise

Binning



- Read out 4 pixels as one
- Increases SNR by 2x
- Decreases read time by 2 or 4x
- Decreases resolution by 2x

Beating the read-out noise EMCCD



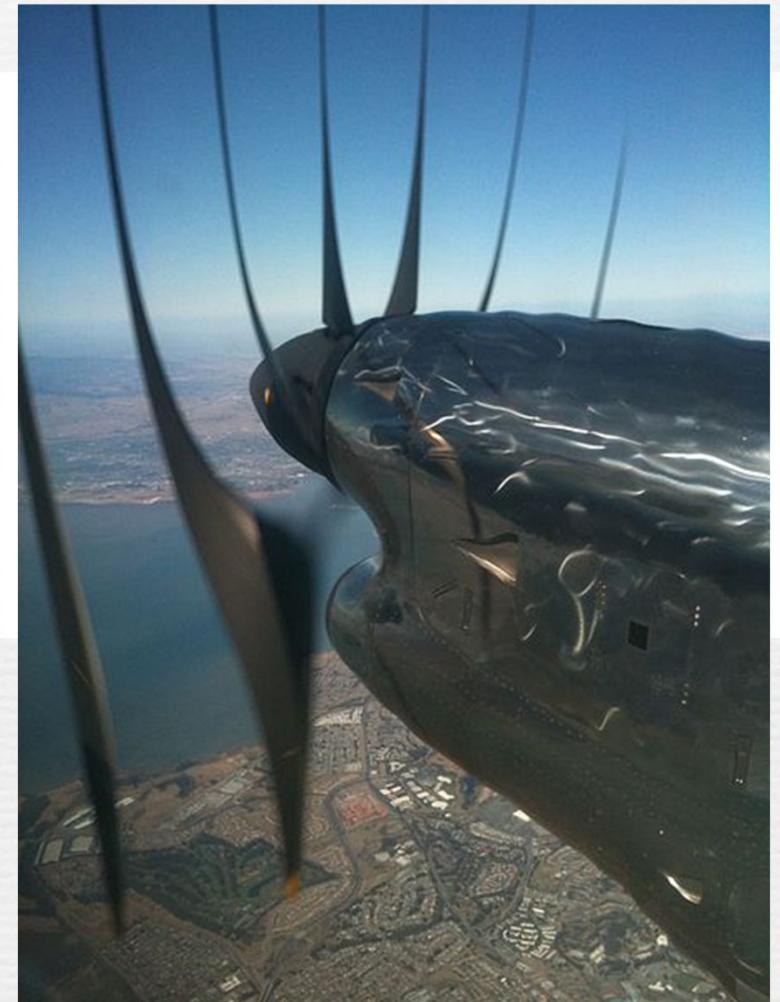
EMCCD result

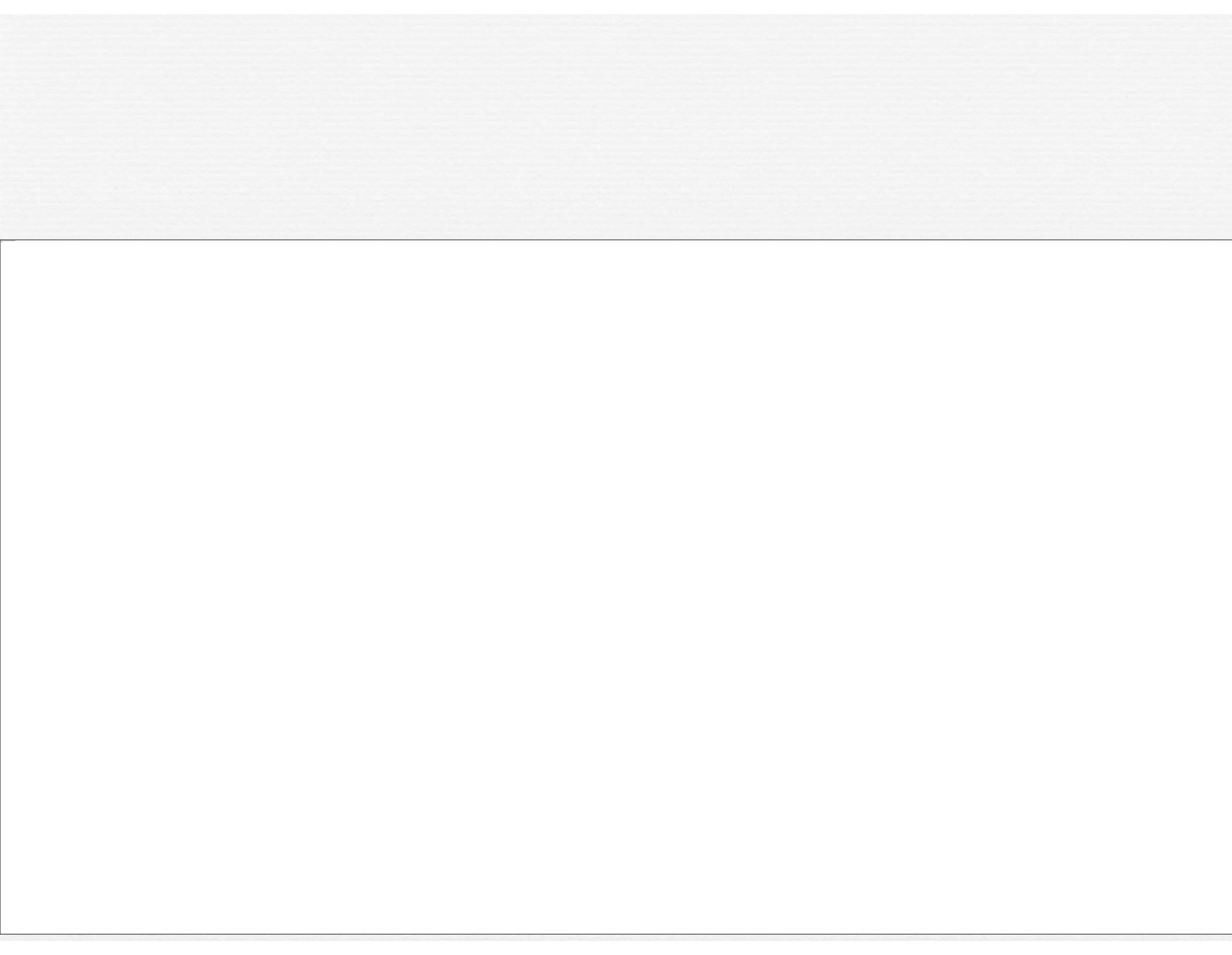
- „ Fast noisy CCD – runs at 30 fps, but 50 e⁻ read noise
- „ Multiply signal by 100-fold – now read noise looks like 0.5 e⁻
- „ Downside – multiplication process adds additional Poisson noise (looks like QE is halved)
- „ Upside – you get to image fast without worrying about read noise

s(cientific)CMOS

< 1.5 electron read-noise!

- 2,000 x 2,000 pixels, 6.5 micron
- 100 fps full frame, subregions up to 25,000 fps
- fixed pattern noise
- binning does not reduce r.o. noise
- global versus rolling shutter





Dynamic Range: How many intensity levels can you distinguish?

- Full well capacity (16 000 e⁻)
- Readout noise: 5e-
- Dynamic range:
 - FWC/readout noise: 3200
 - $0.9 * \text{FWC} / (3 * \text{readout noise}) = 960$
- (Human eye ~ 100)

Bitdepth

- „ Digital cameras have a specified bitdepth = number of gray levels they can record
 - „ 8-bit $\rightarrow 2^8 = 256$ gray levels
 - „ 10-bit $\rightarrow 2^{10} = 1024$ gray levels
 - „ 12-bit $\rightarrow 2^{12} = 4096$ gray levels
 - „ 14-bit $\rightarrow 2^{14} = 16384$ gray levels
 - „ 16-bit $\rightarrow 2^{16} = 65536$ gray levels

Photons and Numbers

- Zero photons collected doesn't result in number zero. Offset can often be changed
- 1 photon does not necessarily equal 1 count in your image – electron conversion factor - depends on camera gain

Measure the electron conversion factor:

When the dominant noise source is Photon Shot noise:

$$\sigma(N) = \sqrt{N}$$

Photon Shot noise

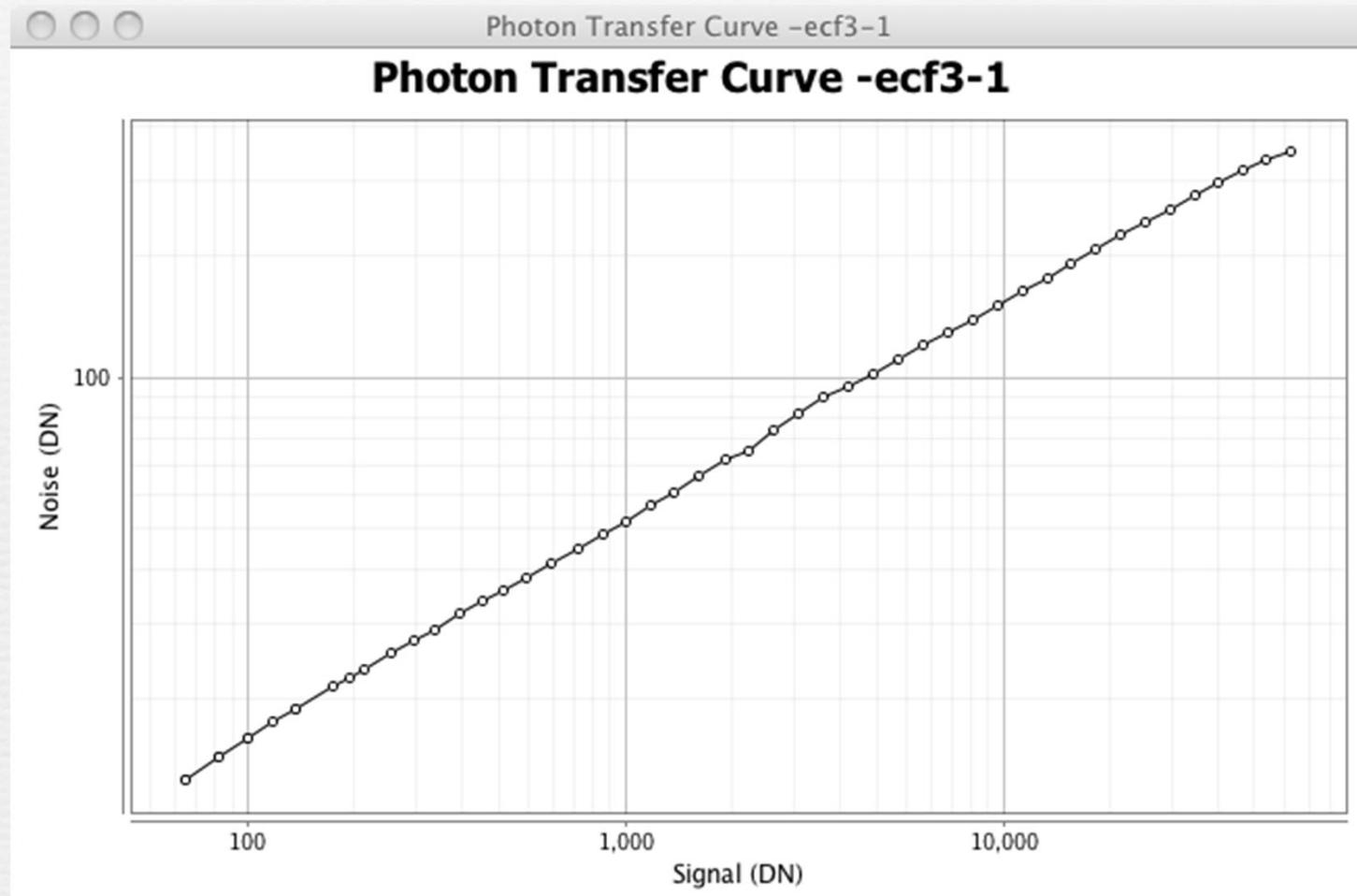
$$N = c \cdot DN$$

c = electron conversion
factor

$$\sigma(N) = c \cdot \sigma(DN)$$

$$c = DN/\sigma^2(DN)$$

Measure Photon Conversion Factor and full well capacity



Photon Transfer Curve from: James R. Janesick, Photon Transfer, DN $\rightarrow \lambda$. SPIE Press, 2007

http://valelab.ucsf.edu/~MM/MMwiki/index.php/Measuring_camera_specifications

Credits and resources:

- n Kurt Thorn (UCSF Nikon Imaging Center)
- n <http://micro.magnet.fsu.edu>
- n James Pawley, Handbook of Biological Confocal Microscopy
- n James R. Janesick, Photon Transfer, DN -> λ . SPIE Press, 2007